# TPS7A84 高电流 (3A)、高效 (1%)、低噪声 (4.4μV$_{RMS}$) LDO 稳压器

1 特性

- 低压降：3 A 时为 180 mV（最大值）
- 整个线路、负载和温度范围内为 1%（最高）精度
- 输出电压噪声：
  – 输出电压为 0.8V 时，噪声为 4.4μV$_{RMS}$
  – 输出电压为 5.0V 时，噪声为 7.7μV$_{RMS}$
- 输入电压范围：
  – 无偏置：1.4V 至 6.5V
  – 有偏置：1.1V 至 6.5V
- ANY-OUT™ 工作电压：
  – 输出电压范围：0.8V 至 3.95V
- 可调节工作电压：
  – 输出电压范围：0.8 V 至 5.0 V
- 电源纹波抑制：
  – 500kHz 时为 40dB
- 出色的负载瞬态响应
- 可调软启动浪涌控制
- 开漏电源正常 (PG) 输出
- 使用 47μF 或更大的陶瓷输出电容器实现稳定运行
- 3.5mm × 3.5mm 20 引脚 VQFN

2 应用

- 宏远程无线电单元 (RRU)
- 室外回程单元
- 有源天线系统 mMIMO (AAS)
- 超声波扫描仪
- 实验室和现场仪表
- 传感器、成像和雷达
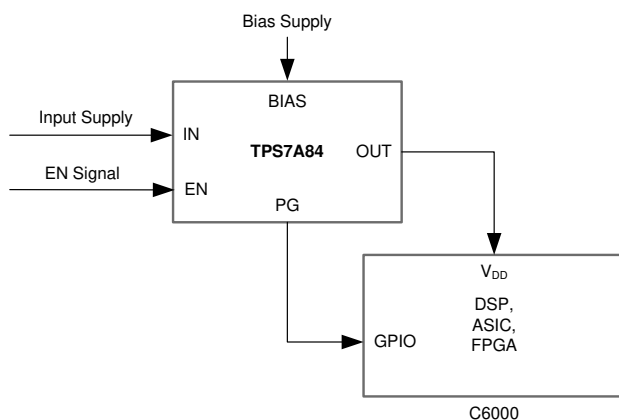
3 说明

TPS7A84 是一款低噪声 (4.4 μV$_{RMS}$)、低压降 (LDO) 线性稳压器，可提供 3A 负载电流，其最高压降仅为 180mV。该器件的输出电压可通过引脚在 0.8V 至 3.95V 的范围内进行编程并可通过外部电阻分压器在 0.8V 至 5.0V 范围内进行调节。

TPS7A84 将低噪声 (4.4μV$_{RMS}$)、高 PSRR 和高输出电流能力融为一体，非常适合为高速通信、视频、医疗或测试和测量应用中的噪声敏感型组件供电。TPS7A84 的高性能可限制电源生成的相位噪声和时钟抖动，非常适合为高性能串行器和解串器 (SerDes)、模数转换器 (ADC)、数模转换器 (DAC) 以及射频 (RF) 组件供电。RF 放大器尤其受益于该器件的高性能和 5.0V 输出性能。
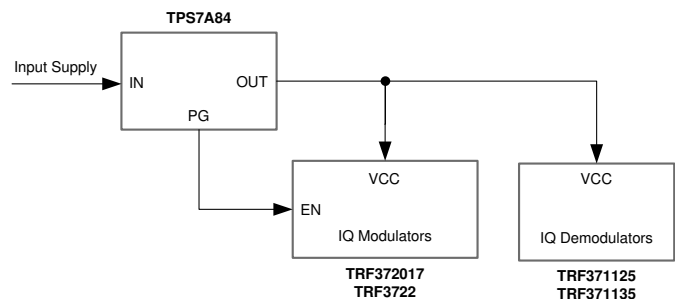
对于需要以低输入电压、低输出 (LILO) 电压运行的数字负载 [如特定用途集成电路 (ASIC)、现场可编程门阵列 (FPGA) 以及数字信号处理器 (DSP)]，TPS7A84 优异的精度特性（负载和温度范围内的精度为 0.75%）、远程感测、出色的瞬态性能以及软启动功能可确保最优系统性能。

TPS7A84 器件的多功能性使其适用于许多严苛应用。

器件信息[(1)]

器件型号	封装	封装尺寸（标称值）
TPS7A84	VQFN (20)	3.50mm × 3.50mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

为数字负载供电

为射频组件供电

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注：以前版本的页码可能与当前版本的页码不同

5 Pin Configurations and Functions
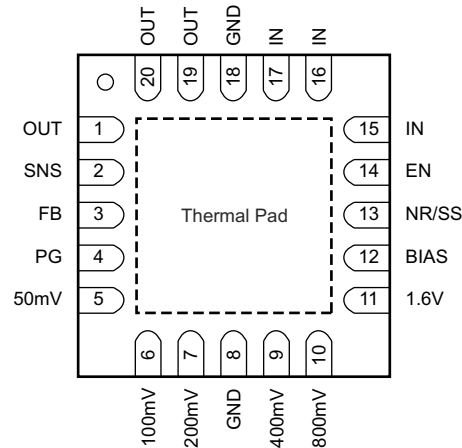
图 5-1. RGR Package, 3.5-mm × 3.5-mm, 20-Pin VQFN, Top View

表 5-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
50mV	5	I	ANY-OUT voltage setting pins. Connect these pins to ground, SNS, or leave floating. Connecting these pins to ground increases the output voltage, whereas connecting these pins to SNS increases the resolution of the ANY-OUT network but decreases the range of the network; multiple pins can be simultaneously connected to GND or SNS to select the desired output voltage. Leave these pins floating (open) when not in use. See the *ANY-OUT Programmable Output Voltage* section for additional details.
100mV	6		
200mV	7		
400mV	9		
800mV	10		
1.6V	11		
BIAS	12	I	BIAS supply voltage. This pin enables the use of low-input voltage, low-output (LILO) voltage conditions (that is, V_{IN} = 1.2 V, V_{OUT} = 1 V) to reduce power dissipation across the die. The use of a BIAS voltage improves dc and ac performance for $V_{IN} \leqslant$ 2.2 V. A 10-μF capacitor or larger must be connected between this pin and ground. If not used, this pin must be left floating or tied to ground.
EN	14	I	Enable pin. Driving this pin to logic high enables the device; driving this pin to logic low disables the device. If enable functionality is not required, this pin must be connected to IN. If enable functionality is required, V_{EN} must always be high after V_{IN} is established when a BIAS supply is used. See the *Sequencing Requirements* section for more details.
FB	3	I	Feedback pin connected to the error amplifier. Although not required, a 10-nF feed-forward capacitor from FB to OUT (as close to the device as possible) is recommended to maximize ac performance. The use of a feed-forward capacitor can disrupt PG (power good) functionality. See the *ANY-OUT Programmable Output Voltage* and *Adjustable Operation* sections for more details.
GND	8, 18	—	Ground pin. These pins must be connected to ground, the thermal pad, and each other with a low-impedance connection.
IN	15-17	I	Input supply voltage pin. A 47-μF or larger ceramic capacitor (25 μF or greater of capacitance) from IN to ground is recommended to reduce the impedance of the input supply. Place the input capacitor as close to the input as possible. See the *Input and Output Capacitor Requirements (C_{IN} and C_{OUT})* section for more details.
NR/SS	13	—	Noise-reduction and soft-start pin. Connecting an external capacitor between this pin and ground reduces reference voltage noise and also enables the soft-start function. Although not required, a 10-nF or larger capacitor is recommended to be connected from NR/SS to GND (as close to the pin as possible) to maximize ac performance. See the *Noise-Reduction and Soft-Start Capacitor ($C_{NR/SS}$)* section for more details.
OUT	1, 19, 20	O	Regulated output pin. A 47-μF or larger ceramic capacitor (25 μF or greater of capacitance) from OUT to ground is required for stability and must be placed as close to the output as possible. Minimize the impedance from the OUT pin to the load. See the *Input and Output Capacitor Requirements (C_{IN} and C_{OUT})* section for more details.
PG	4	O	Active-high, power-good pin. An open-drain output indicates when the output voltage reaches 89.3% of the target. The use of a feed-forward capacitor can disrupt PG (power good) functionality. See the *Power-Good Function* section for more details.
SNS	2	I	Output voltage sense input pin. This pin connects the internal R_1 resistor to the output. Connect this pin to the load side of the output trace only if the ANY-OUT feature is used. If the ANY-OUT feature is not used, leave this pin floating. See the *ANY-OUT Programmable Output Voltage* and *Adjustable Operation* sections for more details.
Thermal pad		—	Connect the thermal pad to a large-area ground plane. The thermal pad is internally connected to GND.

Product Folder Links: *TPS7A84*

6 Specifications

6.1 Absolute Maximum Ratings

over junction temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
Voltage	IN, BIAS, PG, EN	– 0.3	7.0	V
	IN, BIAS, PG, EN (5% duty cycle, pulse duration = 200 µs)	– 0.3	7.5	
	SNS, OUT	– 0.3	V_{IN} + 0.3[2]	
	NR/SS, FB	– 0.3	3.6	
	50mV, 100mV, 200mV, 400mV, 800mV, 1.6V	– 0.3	V_{OUT} + 0.3	
Current	OUT	Internally limited		A
	PG (sink current into device)		5	mA
Temperature	Operating junction, T_J	– 55	150	°C
	Storage, T_{stg}	– 55	150	

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The absolute maximum rating is V_{IN} + 0.3 V or 7.0 V, whichever is smaller.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101[2]	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

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6.3 Recommended Operating Conditions

over junction temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Input supply voltage range	1.1		6.5	V
V_{BIAS}	Bias supply voltage range[1]	3.0		6.5	V
V_{OUT}	Output voltage range[2]	0.8		5	V
V_{EN}	Enable voltage range	0		V_{IN}	V
I_{OUT}	Output current	0		3	A
C_{IN}	Input capacitor	10	47		µF
C_{OUT}	Output capacitor	47	47 || 10 || 10[3]		µF
R_{PG}	Power-good pullup resistance	10		100	kΩ
$C_{NR/SS}$	NR/SS capacitor		10		nF
C_{FF}	Feed-forward capacitor		10		nF
R_1	Top resistor value in feedback network for adjustable operation		12.1[4]		kΩ
R_2	Bottom resistor value in feedback network for adjustable operation			160[5]	kΩ
T_J	Operating junction temperature	–40		125	°C

(1) BIAS supply is required when the V_{IN} supply is below 1.4 V. Conversely, no BIAS supply is required when the V_{IN} supply is higher than or equal to 1.4 V. A BIAS supply helps improve dc and ac performance for $V_{IN} \leqslant$ 2.2 V.
(2) This output voltage range does not include device accuracy or accuracy of the feedback resistors.
(3) The recommended output capacitors are selected to optimize PSRR for the frequency range of 400 kHz to 700 kHz. This frequency range is a typical value for dc-dc supplies.
(4) The 12.1-kΩ resistor is selected to optimize PSRR and noise by matching the internal R_1 value.
(5) The upper limit for the R_2 resistor is to ensure accuracy by making the current through the feedback network much larger than the leakage current into the feedback node.

6.4 Thermal Information

THERMAL METRIC[1]		TPS7A84	UNIT
		RGR (VQFN)	
		20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	35.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	47.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	12.3	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.5	°C/W
ψ_{JB}	Junction-to-board characterization parameter	12.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	1.0	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

over operating junction temperature range (T_J = – 40°C to +125°C), V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V[2], OUT connected to 50 Ω to GND[3], V_{EN} = 1.1 V, C_{IN} = 10 μF, C_{OUT} = 47 μF, $C_{NR/SS}$ without C_{FF}, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted); typical values are at T_J = 25°C

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IN}	Input supply voltage range[1]			1.1		6.5	V
V_{BIAS}	Bias supply voltage range[1]		V_{IN} = 1.1 V	3.0		6.5	V
V_{FB}	Feedback voltage				0.8		V
$V_{NR/SS}$	NR/SS pin voltage				0.8		V
$V_{UVLO1(IN)}$	Input supply UVLO with BIAS		V_{IN} rising with V_{BIAS} = 3.0 V		1.02	1.085	V
$V_{HYS1(IN)}$	$V_{UVLO1(IN)}$ hysteresis		V_{BIAS} = 3.0 V		320		mV
$V_{UVLO2(IN)}$	Input supply UVLO without BIAS		V_{IN} rising		1.31	1.39	V
$V_{HYS2(IN)}$	$V_{UVLO2(IN)}$ hysteresis				253		mV
$V_{UVLO(BIAS)}$	Bias supply UVLO		V_{BIAS} rising, V_{IN} = 1.1 V		2.83	2.9	V
$V_{HYS(BIAS)}$	$V_{UVLO(BIAS)}$ hysteresis		V_{IN} = 1.1 V		290		mV
V_{OUT}	Output voltage	Range	Using the ANY-OUT pins	0.8 – 1.0%		3.95 + 1.0%	V
			Using external resistors[4]	0.8 – 1.0%		5.0 + 1.0%	
		Accuracy[4] [5]	0.8 V ⩽ V_{OUT} ⩽ 5 V, 5 mA ⩽ I_{OUT} ⩽ 3 A, over V_{IN}	– 1.0%		1.0%	
		Accuracy with BIAS	V_{IN} = 1.1 V, 5 mA ⩽ I_{OUT} ⩽ 3 A, 3.0 V ⩽ V_{BIAS} ⩽ 6.5 V	– 0.75%		0.75%	
$\Delta V_{OUT}/\Delta V_{IN}$	Line regulation		I_{OUT} = 5 mA, 1.4 V ⩽ V_{IN} ⩽ 6.5 V		0.0035		mV/V
$\Delta V_{OUT}/\Delta I_{OUT}$	Load regulation		5 mA ⩽ I_{OUT} ⩽ 3 A, 3.0 V ⩽ V_{BIAS} ⩽ 6.5 V, V_{IN} = 1.1 V		0.07		mV/A
			5 mA ⩽ I_{OUT} ⩽ 3 A		0.08		
			5 mA ⩽ I_{OUT} ⩽ 3 A, V_{OUT} = 5.0 V		0.4		
V_{DO}	Dropout voltage		V_{IN} = 1.4 V, I_{OUT} = 3 A, V_{FB} = 0.8 V – 3%		156	250	mV
			V_{IN} = 5.4 V, I_{OUT} = 3 A, V_{FB} = 0.8 V – 3%		220	340	
			V_{IN} = 1.1 V, V_{BIAS} = 5.0 V, I_{OUT} = 3 A, V_{FB} = 0.8 V – 3%		110	180	
I_{LIM}	Output current limit		V_{OUT} forced at 0.9 × $V_{OUT(nom)}$, V_{IN} = $V_{OUT(nom)}$ + 0.4 V	3.7	4.2	4.7	A
I_{SC}	Short-circuit current limit		R_{LOAD} = 20 mΩ		1.0		A
I_{GND}	GND pin current		V_{IN} = 6.5 V, I_{OUT} = 5 mA		2.8	4	mA
			V_{IN} = 1.4 V, I_{OUT} = 3 A		4.2	5.5	
			Shutdown, PG = open, V_{IN} = 6.5 V, V_{EN} = 0.5 V			25	µA
I_{EN}	EN pin current		V_{IN} = 6.5 V, V_{EN} = 0 V and 6.5 V	– 0.1		0.1	µA
I_{BIAS}	BIAS pin current		V_{IN} = 1.1 V, V_{BIAS} = 6.5 V, $V_{OUT(nom)}$ = 0.8 V, I_{OUT} = 3 A		2.3	3.5	mA
$V_{IL(EN)}$	EN pin low-level input voltage (disable device)			0		0.5	V
$V_{IH(EN)}$	EN pin high-level input voltage (enable device)			1.1		6.5	V
$V_{IT(PG)}$	PG pin threshold		For falling V_{OUT}	82% × V_{OUT}	88.3% × V_{OUT}	93% × V_{OUT}	V
$V_{HYS(PG)}$	PG pin hysteresis		For rising V_{OUT}		1% × V_{OUT}		V
$V_{OL(PG)}$	PG pin low-level output voltage		V_{OUT} < $V_{IT(PG)}$, I_{PG} = – 1 mA (current into device)			0.4	V
$I_{lkg(PG)}$	PG pin leakage current		V_{OUT} > $V_{IT(PG)}$, V_{PG} = 6.5 V			1	µA
$I_{NR/SS}$	NR/SS pin charging current		$V_{NR/SS}$ = GND, V_{IN} = 6.5 V	4.0	6.2	9.0	µA
I_{FB}	FB pin leakage current		V_{IN} = 6.5 V	– 100		100	nA

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6.5 Electrical Characteristics (continued)

over operating junction temperature range (T_J = – 40°C to +125°C), V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V[2], OUT connected to 50 Ω to GND[3], V_{EN} = 1.1 V, C_{IN} = 10 μF, C_{OUT} = 47 μF, $C_{NR/SS}$ without C_{FF}, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted); typical values are at T_J = 25°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
PSRR	Power-supply ripple rejection	V_{IN} – V_{OUT} = 0.4 V, I_{OUT} = 3 A, $C_{NR/SS}$ = 100 nF, C_{FF} = 10 nF, C_{OUT} = 47 μF ‖ 10 μF ‖ 10 μF	f = 10 kHz, V_{OUT} = 0.8 V, V_{BIAS} = 5.0 V		42		dB
			f = 500 kHz, V_{OUT} = 0.8 V, V_{BIAS} = 5.0 V		39		
			f = 10 kHz, V_{OUT} = 5.0 V		40		
			f = 500 kHz, V_{OUT} = 5.0 V		25		
V_n	Output noise voltage	BW = 10 Hz to 100 kHz, V_{IN} = 1.1 V, V_{OUT} = 0.8 V, V_{BIAS} = 5.0 V, I_{OUT} = 3 A, $C_{NR/SS}$ = 100 nF, C_{FF} = 10 nF, C_{OUT} = 47 μF ‖ 10 μF ‖ 10 μF			4.4		μV_{RMS}
		BW = 10 Hz to 100 kHz, V_{OUT} = 5.0 V, I_{OUT} = 3 A, $C_{NR/SS}$ = 100 nF, C_{FF} = 10 nF, C_{OUT} = 47 μF ‖ 10 μF ‖ 10 μF			7.7		
T_{sd}	Thermal shutdown temperature	Shutdown, temperature increasing			160		°C
		Reset, temperature decreasing			140		
T_J	Operating junction temperature			– 40		125	°C

(1) BIAS supply is required when the V_{IN} supply is below 1.4 V. Conversely, no BIAS supply is required when the V_{IN} supply is higher than or equal to 1.4 V. A BIAS supply helps improve dc and ac performance for V_{IN} ⩽ 2.2 V.
(2) $V_{OUT(nom)}$ is the calculated V_{OUT} target value from the ANY-OUT in a fixed configuration. In an adjustable configuration, $V_{OUT(nom)}$ is the expected V_{OUT} value set by the external feedback resistors.
(3) This 50-Ω load is disconnected when the test conditions specify an I_{OUT} value.
(4) When the device is connected to external feedback resistors at the FB pin, external resistor tolerances are not included.
(5) The device is not tested under conditions where V_{IN} > V_{OUT} + 1.7 V and I_{OUT} = 3 A, because the power dissipation is higher than the maximum rating of the package.
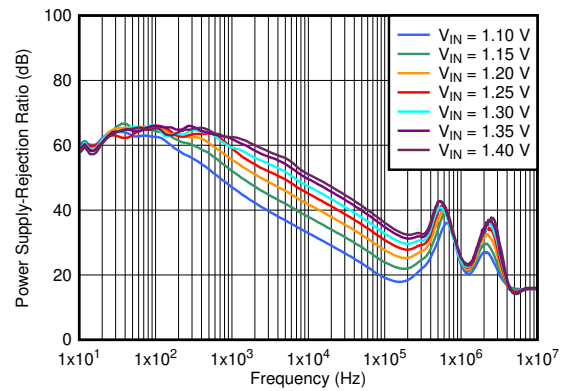
6.6 Typical Characteristics

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(NOM)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(NOM)}$ = 0.8 V, V_{EN} = 1.1 V, C_{OUT} = 47 μF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)
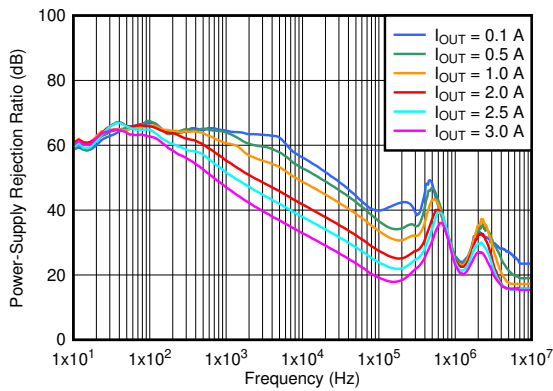
V_{IN} = 1.1 V, V_{BIAS} = 5 V, C_{OUT} = 47 μF ǁ 10 μF ǁ 10 μF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

图 6-1. PSRR vs Frequency and I_{OUT}

I_{OUT} = 3 A, V_{BIAS} = 5 V, C_{OUT} = 47 μF ǁ 10 μF ǁ 10 μF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

图 6-2. PSRR vs Frequency and V_{IN} With Bias
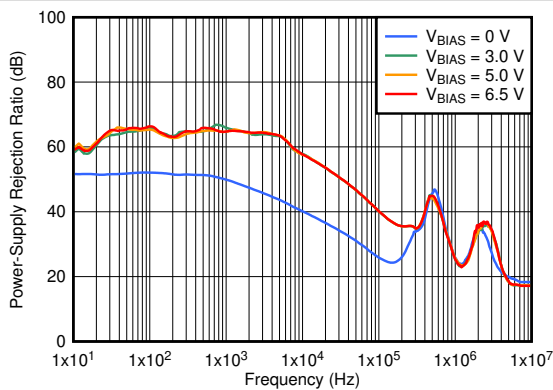
V_{IN} = 1.4 V, I_{OUT} = 1 A, C_{OUT} = 47 μF ǁ 10 μF ǁ 10 μF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

图 6-3. PSRR vs Frequency and V_{BIAS}
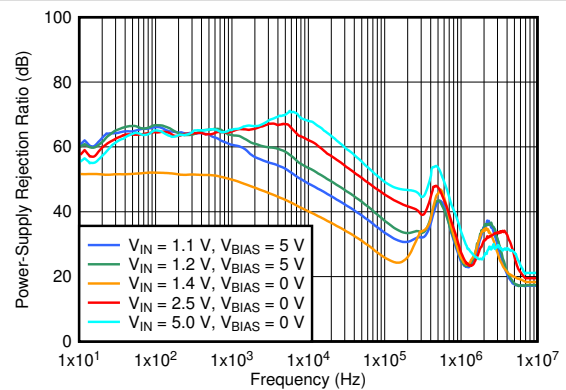
I_{OUT} = 1 A, C_{OUT} = 47 μF ǁ 10 μF ǁ 10 μF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

图 6-4. PSRR vs Frequency and V_{IN}
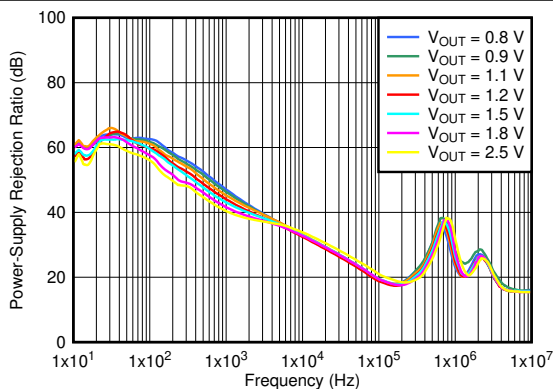
V_{IN} = V_{OUT} + 0.3 V, V_{BIAS} = 5.0 V, I_{OUT} = 3 A, C_{OUT} = 47 μF ǁ 10 μF ǁ 10 μF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

图 6-5. PSRR vs Frequency and V_{OUT} With Bias
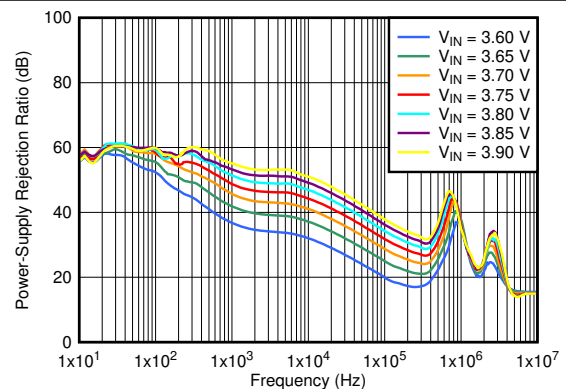
I_{OUT} = 3 A, C_{OUT} = 47 μF ǁ 10 μF ǁ 10 μF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

图 6-6. PSRR vs Frequency and V_{IN} for V_{OUT} = 3.3 V

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6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(NOM)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(NOM)}$ = 0.8 V, V_{EN} = 1.1 V, C_{OUT} = 47 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)
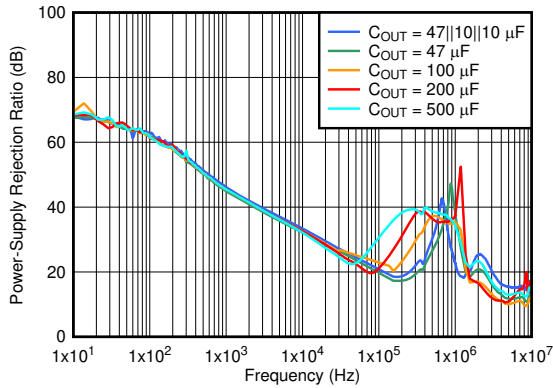
V_{IN} = V_{OUT} + 0.3 V, V_{OUT} = 1 V, I_{OUT} = 3 A, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

图 6-7. PSRR vs Frequency and C_{OUT}
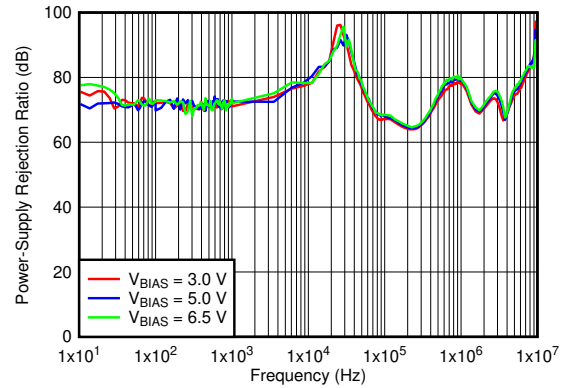
V_{IN} = V_{OUT} + 0.3 V, V_{OUT} = 1 V, I_{OUT} = 3 A, C_{OUT} = 47 µF || 10 µF || 10 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

图 6-8. V_{BIAS} PSRR vs Frequency
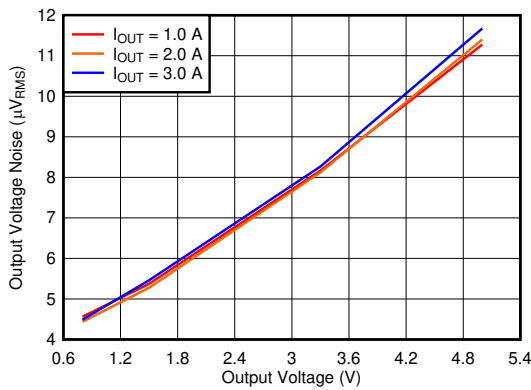
V_{IN} = V_{OUT} + 0.3 V and V_{BIAS} = 5 V for V_{OUT} ⩽ 2.2 V, C_{OUT} = 47 µF || 10 µF || 10 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

图 6-9. Output Voltage Noise vs Output Voltage
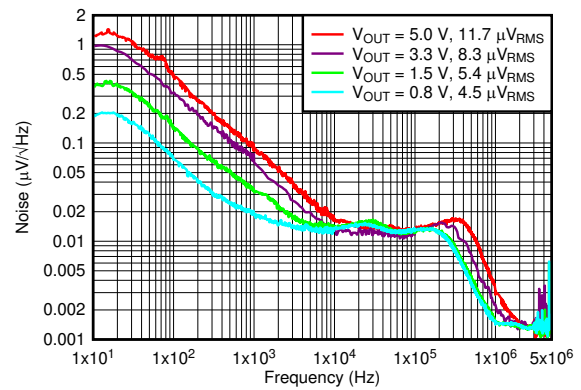
V_{IN} = V_{OUT} + 0.3 V and V_{BIAS} = 5 V for V_{OUT} ⩽ 2.2 V, I_{OUT} = 3 A, C_{OUT} = 47 µF || 10 µF || 10 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

图 6-10. Output Noise vs Frequency and Output Voltage
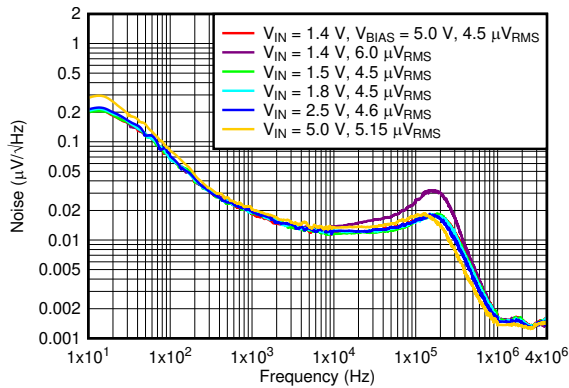
I_{OUT} = 3 A, C_{OUT} = 47 µF || 10 µF || 10 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

图 6-11. Output Noise vs Frequency and Input Voltage
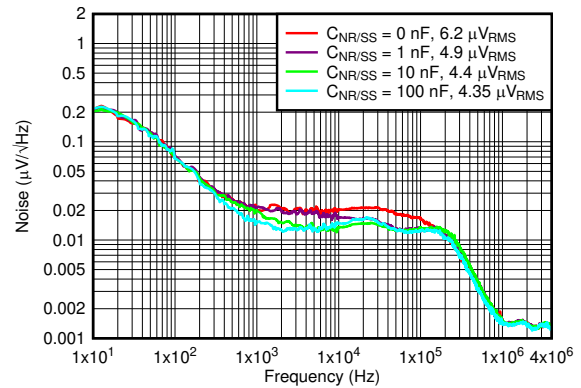
V_{IN} = V_{OUT} + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 3 A, C_{OUT} = 47 µF || 10 µF || 10 µF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

图 6-12. Output Noise vs Frequency and $C_{NR/SS}$

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6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(NOM)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(NOM)}$ = 0.8 V, V_{EN} = 1.1 V, C_{OUT} = 47 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)
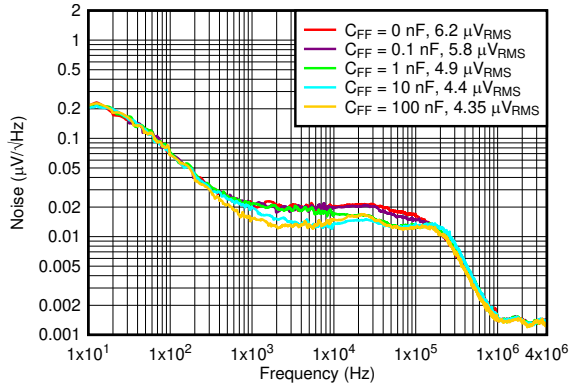
V_{IN} = V_{OUT} + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 3 A, sequencing with a dc/dc converter and PG, C_{OUT} = 47 µF || 10 µF || 10 µF, $C_{NR/SS}$ = 10 nF, RMS noise BW = 10 Hz to 100 kHz

图 6-13. Output Noise vs Frequency and C_{FF}
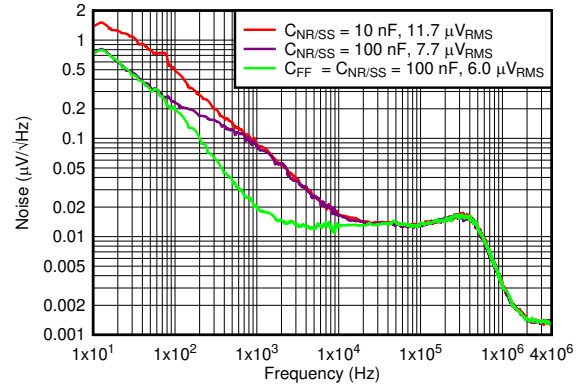
I_{OUT} = 3 A, C_{OUT} = 47 µF || 10 µF || 10 µF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

图 6-14. Output Noise at 5.0-V Output
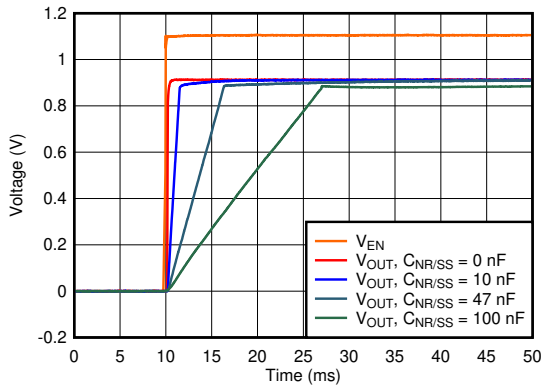
V_{IN} = 1.2 V, V_{OUT} = 0.9 V, V_{BIAS} = 5.0 V, I_{OUT} = 3 A, C_{OUT} = 47 µF || 10 µF || 10 µF, C_{FF} = 10 nF

图 6-15. Start-Up Waveform vs Time and $C_{NR/SS}$
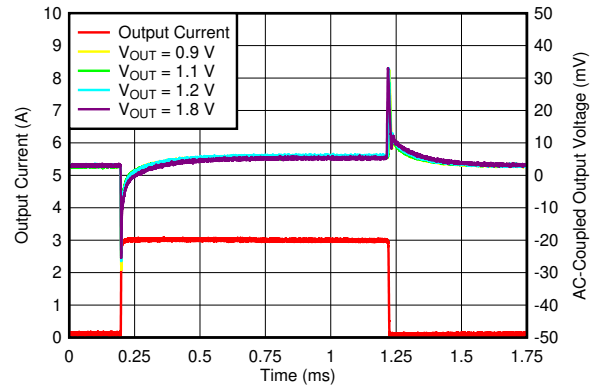
V_{IN} = V_{OUT} + 0.3 V, V_{BIAS} = 5 V, $I_{OUT, DC}$ = 100 mA, slew rate = 1 A/µs, $C_{NR/SS}$ = C_{FF} = 10 nF, C_{OUT} = 47 µF || 10 µF || 10 µF

图 6-16. Load Transient vs Time and V_{OUT} With Bias
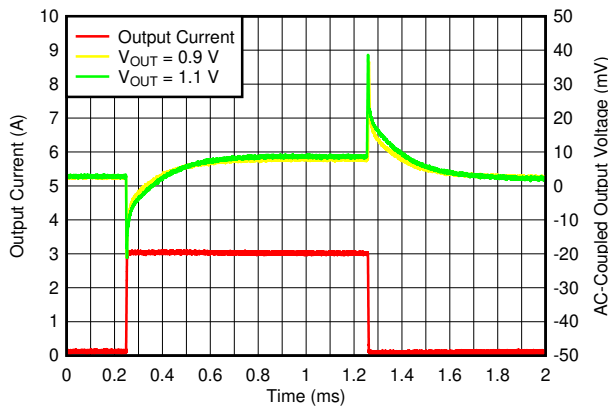
$I_{OUT, DC}$ = 100 mA, C_{OUT} = 47 µF || 10 µF || 10 µF, $C_{NR/SS}$ = C_{FF} = 10 nF, slew rate = 1 A/µs

图 6-17. Load Transient vs Time and V_{OUT} Without Bias
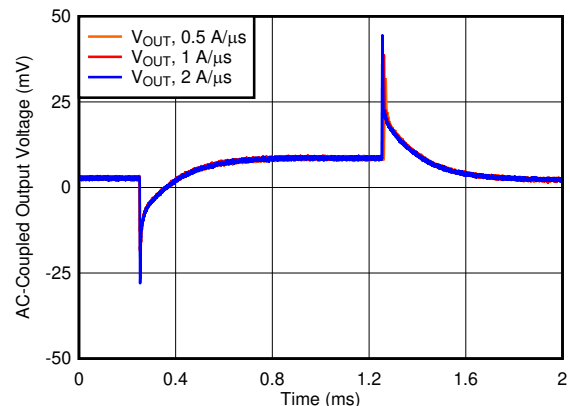
V_{OUT} = 5 V, $I_{OUT, DC}$ = 100 mA, I_{OUT} = 100 mA to 3 A, C_{OUT} = 47 µF || 10 µF || 10 µF, $C_{NR/SS}$ = C_{FF} = 10 nF

图 6-18. Load Transient vs Time and Slew Rate

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6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(NOM)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(NOM)}$ = 0.8 V, V_{EN} = 1.1 V, C_{OUT} = 47 μF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)
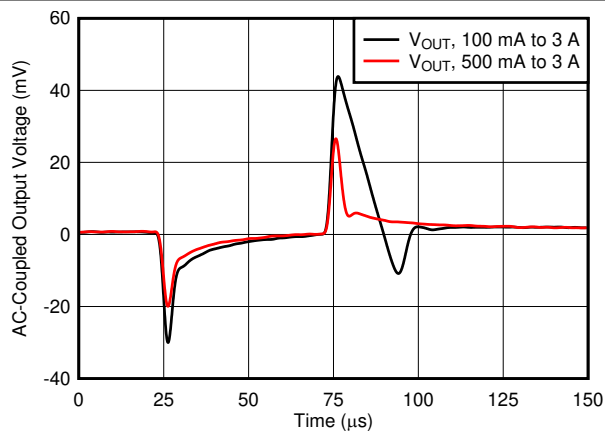
V_{IN} = 1.2 V, V_{BIAS} = 5.0 V, C_{OUT} = 47 μF || 10 μF || 10 μF,
$C_{NR/SS}$ = C_{FF} = 10 nF, slew rate = 1 A/μs

图 6-19. Load Transient vs Time and DC Load (V_{OUT} = 0.9 V)
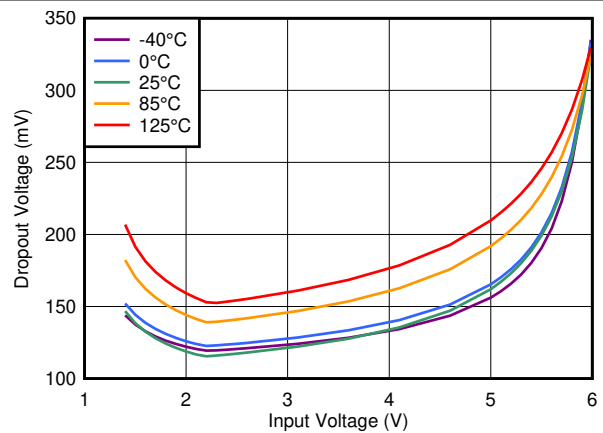
I_{OUT} = 3 A, V_{BIAS} = 0 V

图 6-20. Dropout Voltage vs Input Voltage Without Bias
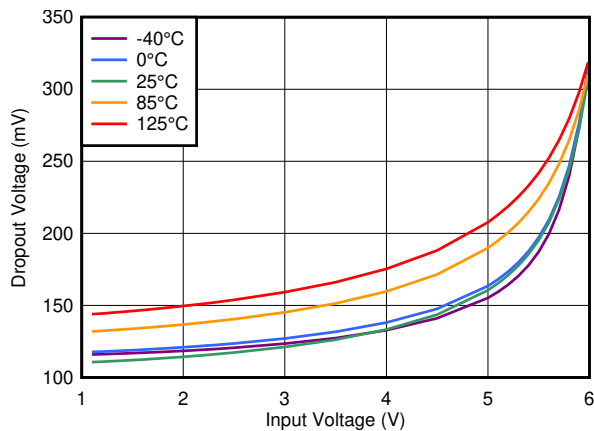
I_{OUT} = 3 A, V_{BIAS} = 6.5 V

图 6-21. Dropout Voltage vs Input Voltage With Bias
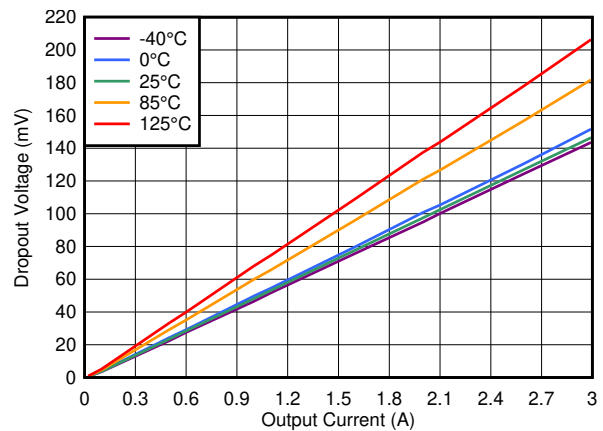
V_{IN} = 1.4 V, V_{BIAS} = 0 V

图 6-22. Dropout Voltage vs Output Current Without Bias
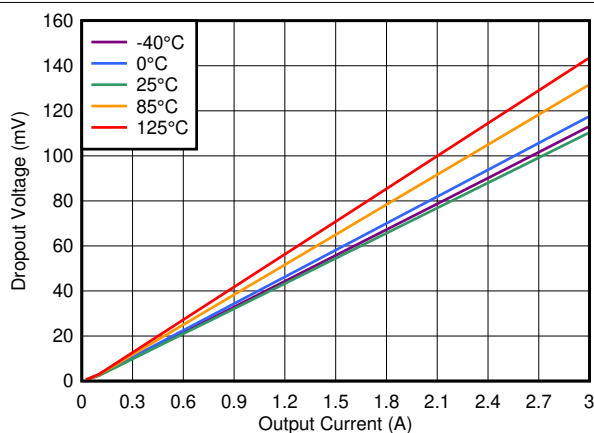
V_{IN} = 1.1 V, V_{BIAS} = 3 V

图 6-23. Dropout Voltage vs Output Current With Bias
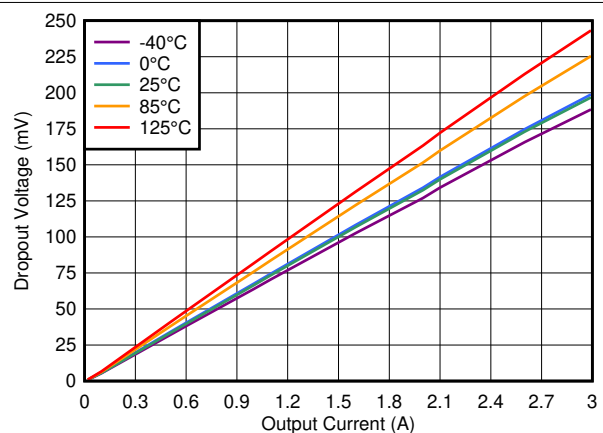
V_{IN} = 5.5 V

图 6-24. Dropout Voltage vs Output Current (High V_{IN})

6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(NOM)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(NOM)}$ = 0.8 V, V_{EN} = 1.1 V, C_{OUT} = 47 μF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)

I_{OUT} = 100 mA to 3 A
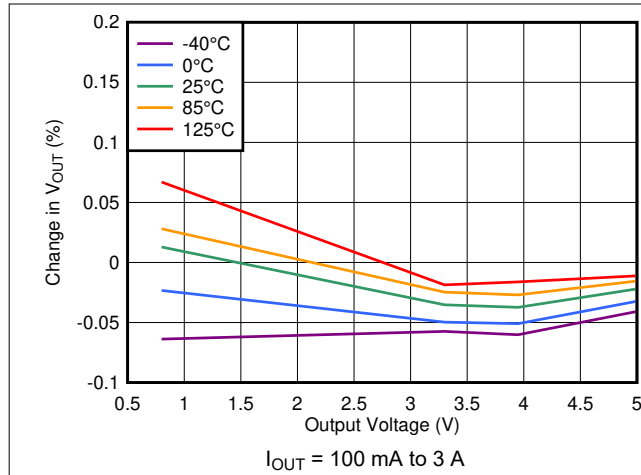
图 6-25. Load Regulation vs Output Voltage

V_{IN} = 1.4 V, V_{BIAS} = 0 V
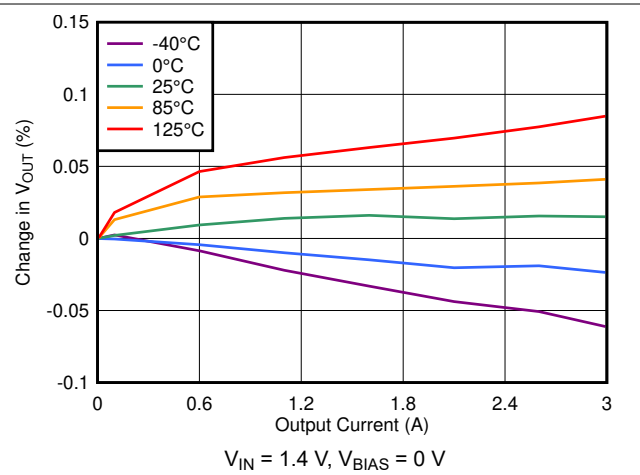
图 6-26. Load Regulation With Bias

V_{IN} = 3.8 V
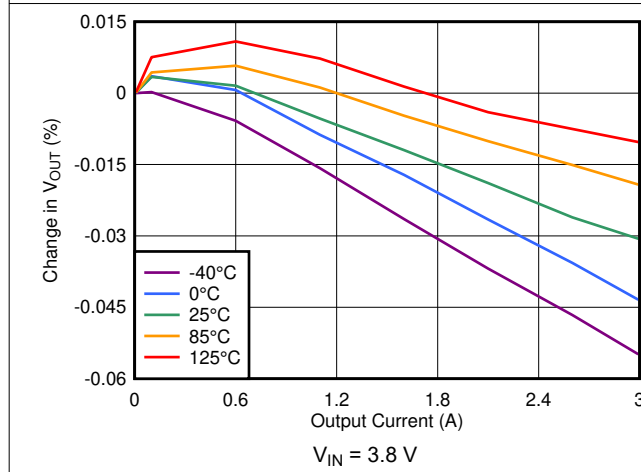
图 6-27. Load Regulation (3.3-V Output)

V_{IN} = 5.5 V
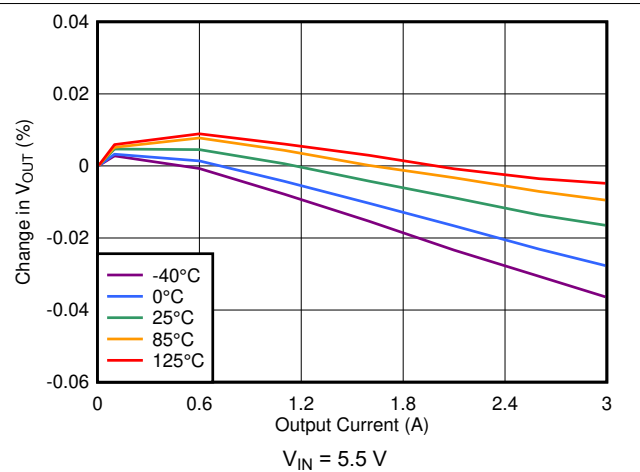
图 6-28. Load Regulation (5-V Output)
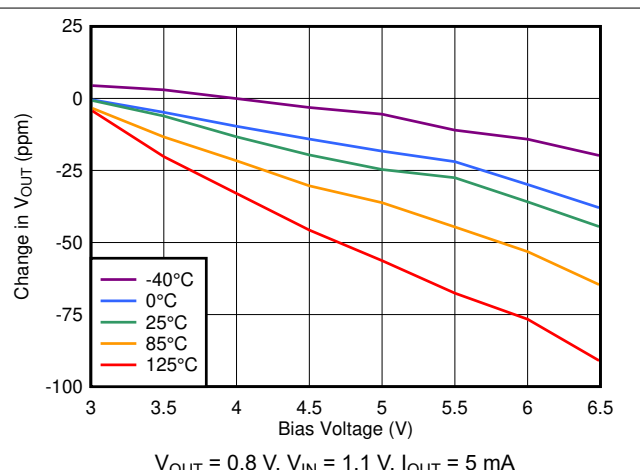
V_{OUT} = 0.8 V, V_{BIAS} = 0 V, I_{OUT} = 5 mA

图 6-29. Line Regulation Without Bias

V_{OUT} = 0.8 V, V_{IN} = 1.1 V, I_{OUT} = 5 mA

图 6-30. Line Regulation Without Bias

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6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(NOM)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(NOM)}$ = 0.8 V, V_{EN} = 1.1 V, C_{OUT} = 47 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)

I_{OUT} = 5 mA
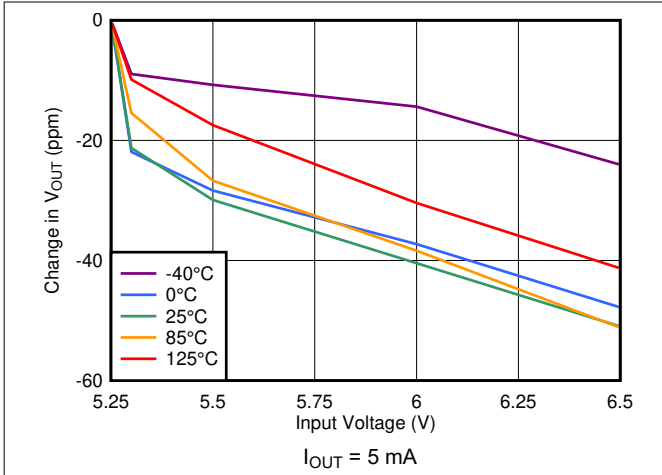
图 6-31. Line Regulation (5-V Output)

V_{BIAS} = 0 V, I_{OUT} = 5 mA
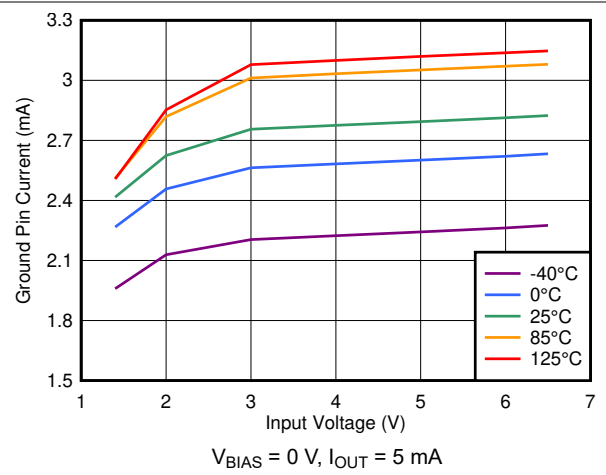
图 6-32. Quiescent Current vs Input Voltage

V_{IN} = 1.1 V, I_{OUT} = 5 mA
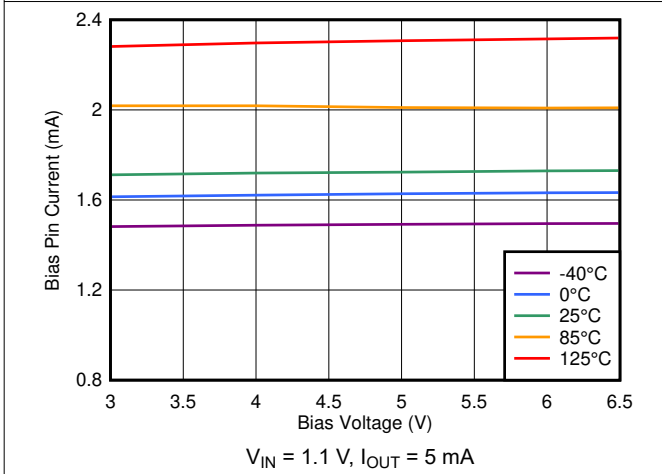
图 6-33. Quiescent Current vs Bias Voltage

V_{BIAS} = 0 V
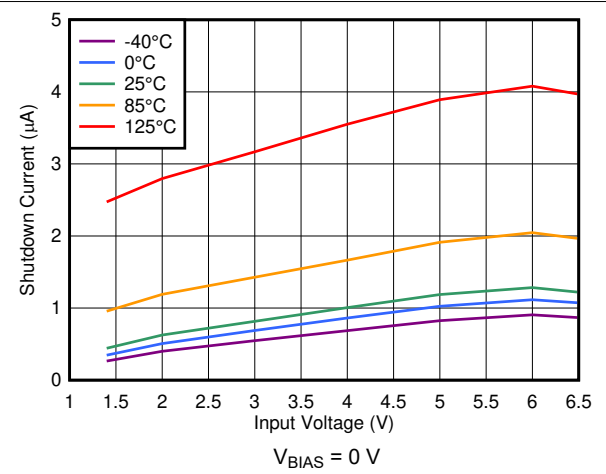
图 6-34. Shutdown Current vs Input Voltage
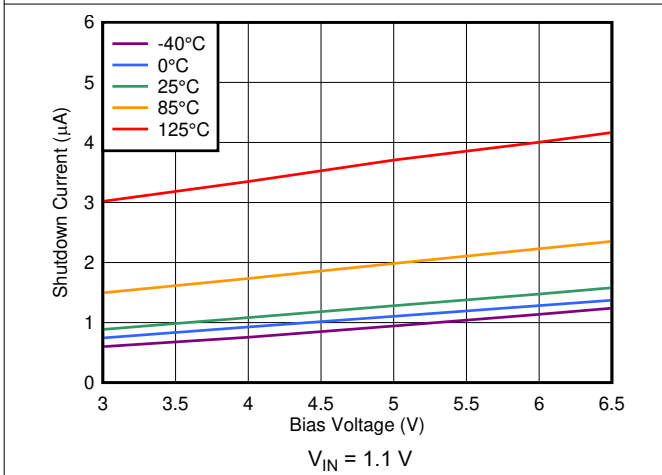
V_{IN} = 1.1 V

图 6-35. Shutdown Current vs Bias Voltage

V_{BIAS} = 0 V
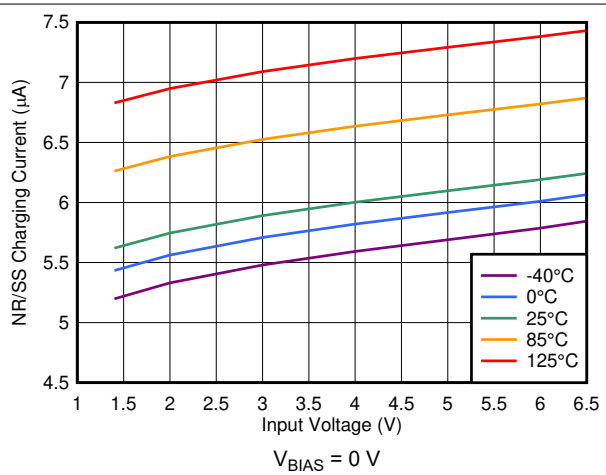
图 6-36. $I_{NR/SS}$ Current vs Input Voltage

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6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(NOM)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(NOM)}$ = 0.8 V, V_{EN} = 1.1 V, C_{OUT} = 47 μF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)
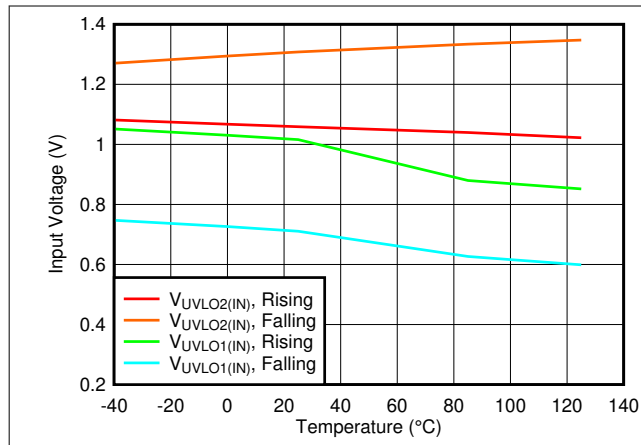
图 6-37. V_{IN} UVLO vs Temperature
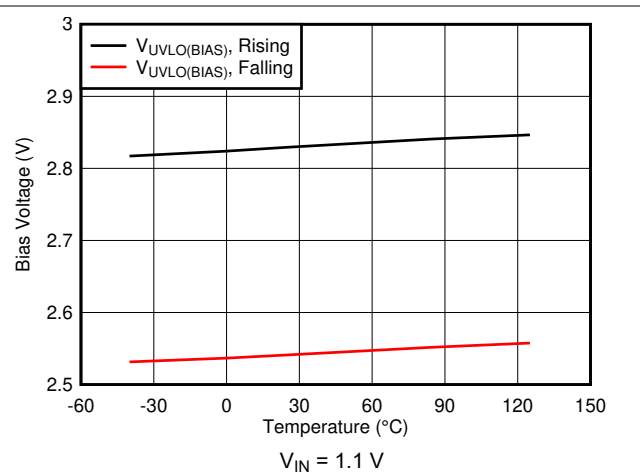
图 6-38. V_{BIAS} UVLO vs Temperature
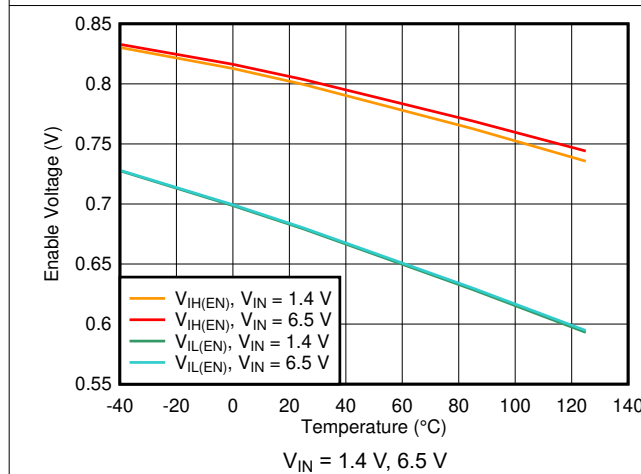
图 6-39. Enable Threshold vs Temperature
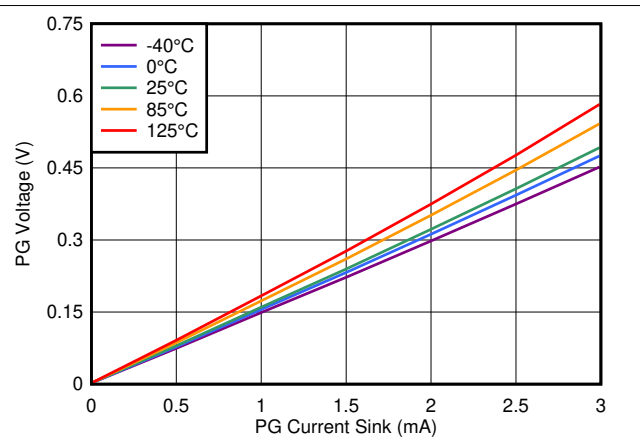
图 6-40. PG Voltage vs PG Current Sink
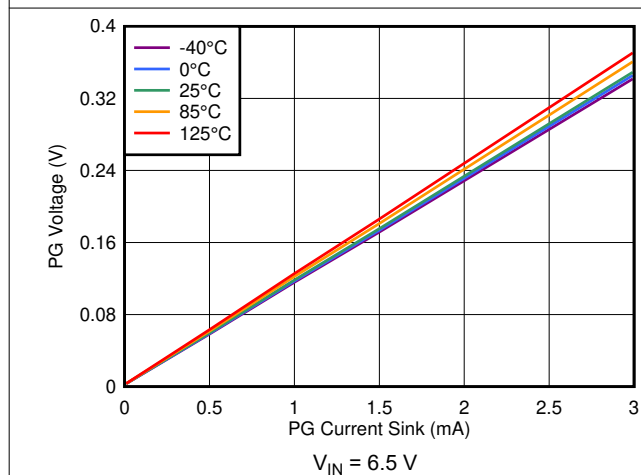
图 6-41. PG Voltage vs PG Current Sink
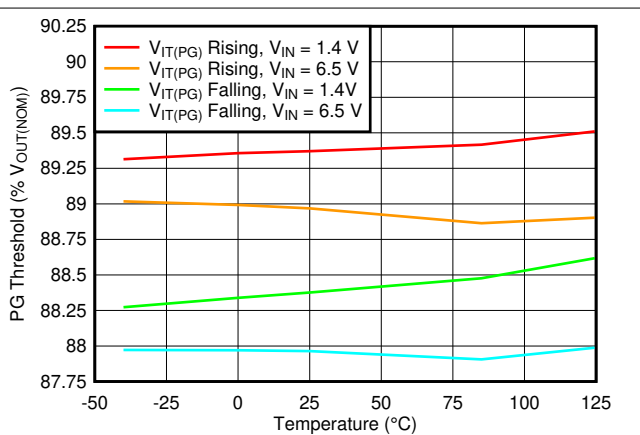
图 6-42. PG Threshold vs Temperature

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7 Detailed Description

7.1 Overview

The TPS7A84 is a high-current (3 A), low-noise (4.4 μV_{RMS}), high accuracy (1%) low-dropout linear voltage regulator (LDO). These features make the device a robust solution to solve many challenging problems in generating a clean, accurate power supply.

The TPS7A84 has several features that make the device useful in a variety of applications. As detailed in the *Functional Block Diagram* section, these features include:

- Low-noise, high-PSRR output
- ANY-OUT resistor network
- Optional bias rail
- Power-good output
- Programmable soft-start
- Foldback current limit
- Enable circuitry
- Active discharge
- Thermal protection

Overall, these features make the TPS7A84 the component of choice because of its versatility and ability to generate a supply for most applications.

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7.2 Functional Block Diagram
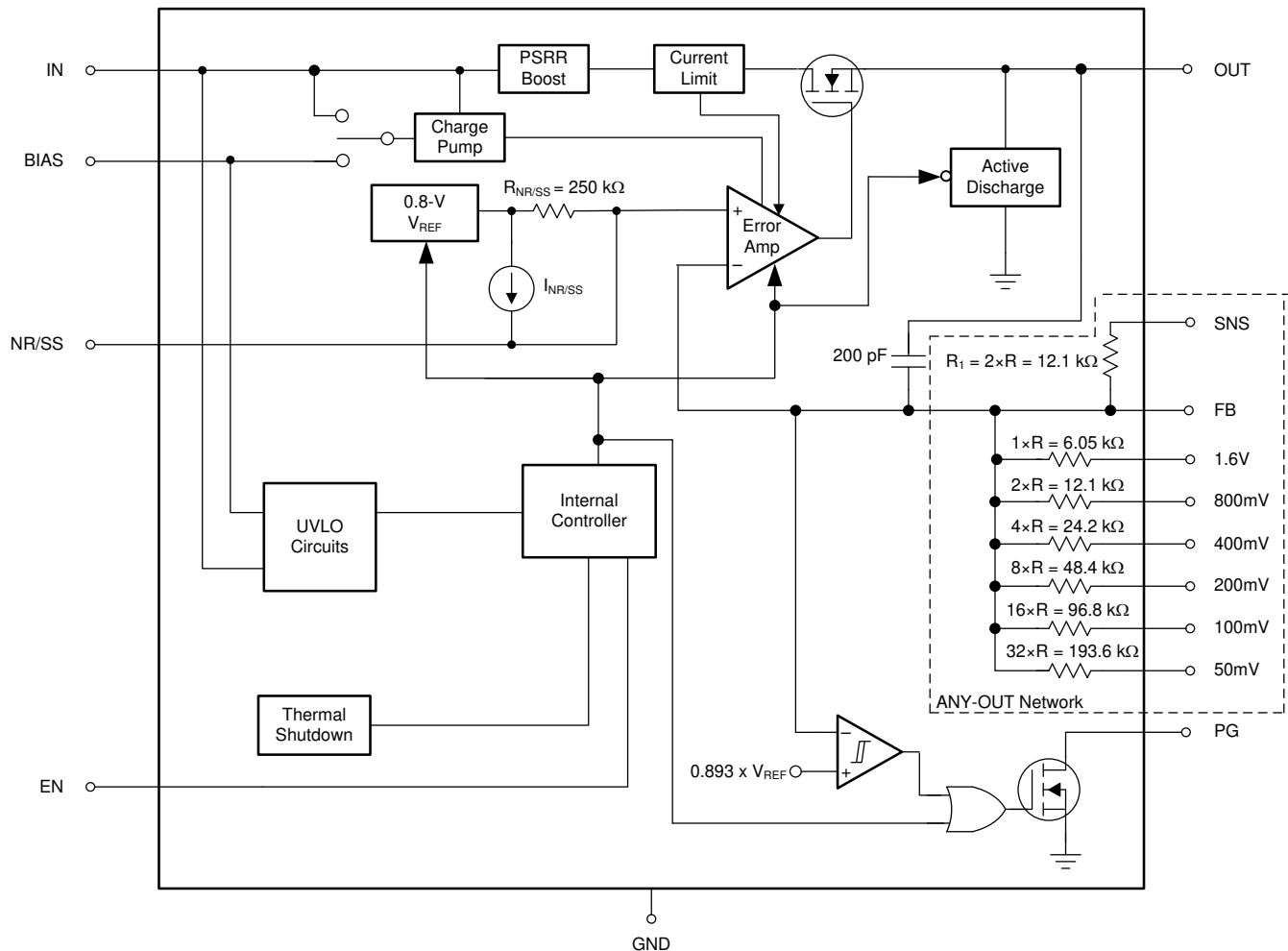
For the ANY-OUT network, the ratios between the values are highly accurate as a result of matching, but the actual resistance can vary significantly from the numbers listed.

7.3 Feature Description

7.3.1 Low-Noise, High-PSRR Output

The TPS7A84 includes a low-noise reference and error amplifier ensuring minimal noise during operation. The NR/SS capacitor ($C_{NR/SS}$) and feed-forward capacitor (C_{FF}) are the easiest way to reduce device noise. $C_{NR/SS}$ filters the noise from the reference and C_{FF} filters the noise from the error amplifier. The noise contribution from the charge pump is minimal. The overall noise of the system at low output voltages can be reduced by using a bias rail because this rail provides more headroom for internal circuitry.

The high power-supply rejection ratio (PSRR) of the TPS7A84 ensures minimal coupling of input supply noise to the output. The PSRR performance is primarily results from a high-bandwidth, high-gain error amplifier and an innovative circuit to boost the PSRR between 200 kHz and 1 MHz.

The combination of a low noise-floor and high PSRR ensure that the device provides a clean supply to the application; see the *Optimizing Noise and PSRR* section for more information on optimizing the noise and PSRR performance.

7.3.2 Integrated Resistance Network (ANY-OUT)

An internal feedback resistance network is provided, allowing the TPS7A84 output voltage to be programmed easily between 0.8 V to 3.95 V with a 50-mV step by tying the ANY-OUT pins to ground. Tying the ANY-OUT pins to SNS increases the resolution but limits the range of the output voltage because the effective value of R_1

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is decreased. Use the ANY-OUT network for excellent accuracy across output voltage and temperature; see the *Application and Implementation* section for more details.

7.3.3 Bias Rail

The device features a bias rail to enable low-input voltage, low-output (LILO) voltage operation by providing power to the internal circuitry of the device. The bias rail is required for operation with V_{IN} < 1.4 V.

An internal power MUX supplies the greater of either the input voltage or the bias voltage to an internal charge pump to power the internal circuitry. Unlike other LDOs that have a bias supply, the TPS7A84 does not have a minimum bias voltage with respect to the input supply because an internal charge pump is used instead.

The internal charge pump multiples the output voltage of the power MUX by a factor of 4 to a maximum of typically 8 V; therefore, using a bias supply with $V_{IN} \leqslant$ 2.2 V is recommended for optimal dc and ac performance. Sequencing requirements exist for when the bias rail is used; see the *Sequencing Requirements* section for more details.

7.3.4 Power-Good Function

The power-good circuit monitors the voltage at the feedback pin to indicate the status of the output voltage. When the feedback pin voltage falls below the PG threshold voltage ($V_{IT(PG)}$ + $V_{HYS(PG)}$, typically 89.3%), the PG pin open-drain output engages and pulls the PG pin close to GND. When the feedback voltage exceeds the $V_{IT(PG)}$ threshold by an amount greater than $V_{HYS(PG)}$ (typically 91.3%), the PG pin becomes high impedance. By connecting a pullup resistor to an external supply, any downstream device can receive power-good as a logic signal that can be used for sequencing. Make sure that the external pullup supply voltage results in a valid logic signal for the receiving device or devices. Using a pullup resistor from 10 kΩ to 100 kΩ is recommended. Using an external voltage detector device such as the TPS3702 is also recommended in applications where more accurate voltage monitoring or overvoltage monitoring is required.

The use of a feed-forward capacitor (C_{FF}) can cause glitches on start-up, and the power-good circuit may not function normally below the minimum input supply range. For more details on the use of the power-good circuitry, see the *Power-Good Operation* section.

7.3.5 Programmable Soft-Start

Soft-start refers to the ramp-up time of the output voltage during LDO turn-on after EN and UVLO exceed the respective threshold voltages. The noise-reduction capacitor ($C_{NR/SS}$) serves a dual purpose of both governing output noise reduction and programming the soft-start ramp time during turn-on. The start-up ramp is monotonic.

The majority of the ramp is linear; however, there is an offset voltage in the error amplifier that can cause a small initial jump in output voltage; see the *Application and Implementation* section on implementing a soft-start.

7.3.6 Internal Current Limit (I_{LIM})

The internal current limit circuit is used to protect the LDO against high-load current faults or shorting events. During a current-limit event, the LDO sources constant current; therefore, the output voltage falls with decreased load impedance. Thermal shutdown can activate during a current limit event because of the high power dissipation typically found in these conditions. To ensure proper operation of the current limit, minimize the inductances to the input and load. Continuous operation in current limit is not recommended.

The foldback current limit crosses 0 A when V_{OUT} < 0 V and prevents the device from turning on into a negatively-biased output. See the *Negatively-Biased Output* section on additional ways to ensure start-up when the TPS7A84 output is pulled below ground.

If V_{OUT} > V_{IN} + 0.3 V, then reverse current can flow from the output to the input. The reverse current can cause damage to the device; therefore, limit this reverse current to 10% of the rated output current of the device. See the *Reverse Current Protection* section for more details.

7.3.7 Enable

The enable pin for the TPS7A84 is active high. The output of the TPS7A84 is turned on when the enable pin voltage is greater than its rising voltage threshold (1.1 V, max), and the output of the TPS7A84 is turned off when the enable pin voltage is less than its falling voltage threshold (0.5 V, min). A voltage less than 0.5 V on the

enable pin disables all internal circuits. At the next turn-on this voltage ensures a normal start-up waveform with in-rush control, provided there is enough time to discharge the output capacitance.

When the enable functionality is not desired, EN must be tied to V_{IN}. However, when the enable functionality is desired, the enable voltage must come after V_{IN} is above $V_{UVLO1(IN)}$ when a BIAS rail is used. See the *Application and Implementation* section for further details.

7.3.8 Active Discharge Circuit

The TPS7A84 has an internal pulldown MOSFET that connects a resistance of several hundred ohms to ground when the device is disabled to actively discharge the output voltage when the device is disabled.

Do not rely on the active discharge circuit for discharging a large amount of output capacitance after the input supply has collapsed because reverse current can possibly flow from the output to the input. This reverse current flow can cause damage to the device. Limit reverse current to no more than 5% of the device rated current for a short period of time.

7.3.9 Undervoltage Lockout (UVLO)

The undervoltage lockout (UVLO) circuit monitors the input and bias voltage (V_{IN} and V_{BIAS}, respectively) to prevent the device from turning on before V_{IN} and V_{BIAS} rise above the lockout voltage. The UVLO circuit also disables the output of the device when V_{IN} or V_{BIAS} fall below the lockout voltage. The UVLO circuit responds quickly to glitches on V_{IN} or V_{BIAS} and attempts to disable the output of the device if either of these rails collapse. As a result of the fast response time of the input supply UVLO circuit, fast and short line transients well below the input supply UVLO falling threshold can cause momentary glitches when asserted or when recovered from the transient. See the *Application and Implementation* section for more details.

7.3.10 Thermal Protection

The TPS7A84 contains a thermal shutdown protection circuit to disable the device when thermal junction temperature (T_J) of the main pass-FET exceeds 160°C (typical). Thermal shutdown hysteresis assures that the LDO resets again (turns on) when the temperature falls to 140°C (typical). The thermal time-constant of the semiconductor die is fairly short, and thus the device cycles on and off when thermal shutdown is reached until the power dissipation is reduced.

For reliable operation, limit the junction temperature to a maximum of 125°C. Operation above 125°C can cause the device to exceed its operational specifications. Although the internal protection circuitry of the TPS7A84 is designed to protect against thermal overload conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the TPS7A84 into thermal shutdown or above a junction temperature of 125°C reduces long-term reliability.

7.4 Device Functional Modes

7.4.1 Operation with 1.1 V ⩽ V_{IN} < 1.4 V

The TPS7A84 requires a bias voltage on the BIAS pin greater than or equal to 3.0 V if the high-current input supply voltage is between 1.1 V to 1.4 V. The bias voltage pin consumes 2.3 mA, nominally.

7.4.2 Operation with 1.4 V ⩽ V_{IN} ⩽ 6.5 V

If the input voltage is equal to or exceeds 1.4 V, no BIAS voltage is required. The TPS7A84 is powered from either the input supply or the BIAS supply, whichever is greater. For higher performance, a BIAS rail is recommended for V_{IN} ⩽ 2.2 V.

7.4.3 Shutdown

Shutting down the device reduces the ground current of the device to a maximum of 25 μA.

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8 Application and Implementation

Note

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客 户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

The TPS7A84 is a linear voltage regulator with an input range of 1.1 V to 6.5 V and an output voltage range of 0.8 V to 5.0 V with a 1% accuracy and a 3-A maximum output current. The TPS7A84 has an integrated charge pump for ease of use and an external bias rail to allow for the lowest dropout across the entire output voltage range.

8.1.1 Recommended Capacitor Types

The TPS7A84 is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input, output, and noise-reduction pin (NR, pin 13). Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and COG-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, ceramic capacitance varies with operating voltage and temperature. As a rule of thumb, derate ceramic capacitors by at least 50%. The input and output capacitors recommended herein account for a capacitance derating of approximately 50%, but at high V_{IN} and V_{OUT} conditions (that is, V_{IN} = 5.5 V to V_{OUT} = 5.0 V) the derating can be greater than 50% and must be taken into consideration.

8.1.2 Input and Output Capacitor Requirements (C_{IN} and C_{OUT})

The TPS7A84 is designed and characterized for operation with ceramic capacitors of 47 μF or greater (22 μF or greater of capacitance) at the output and 10 μF or greater (5 μF or greater of capacitance) at the input. Using at least a 47-μF capacitor is highly recommended at the input to minimize input impedance. Place the input and output capacitors as near as practical to the respective input and output pins to minimize trace parasitics. If the trace inductance from the input supply to the TPS7A84 is high, a fast current transient can cause V_{IN} to ring above the absolute maximum voltage rating and damage the device. This situation can be mitigated by additional input capacitors to dampen the ringing and to keep it below the device absolute maximum ratings.

A combination of multiple output capacitors boosts the high-frequency PSRR, as illustrated in several of the PSRR curves. The combination of one 0805-sized, 47-μF ceramic capacitor in parallel with two 0805-sized, 10-μF ceramic capacitors with a sufficient voltage rating in conjunction with the PSRR boost circuit optimizes PSRR for the frequency range of 400 kHz to 700 kHz, a typical range for dc-dc supply switching frequency. This 47-μF ‖ 10-μF ‖ 10-μF combination also ensures that at high input voltage and high output voltage configurations, the minimum effective capacitance is met. Many 0805-sized, 47-μF ceramic capacitors have a voltage derating of approximately 60% to 80% at 5.0 V, so the addition of the two 10-μF capacitors ensures that the capacitance is at or above 22 μF.

8.1.3 Noise-Reduction and Soft-Start Capacitor ($C_{NR/SS}$)

The TPS7A84 features a programmable, monotonic, voltage-controlled soft-start that is set with an external capacitor ($C_{NR/SS}$).The use of an external $C_{NR/SS}$ is highly recommended, especially to minimize in-rush current into the output capacitors. This soft-start eliminates power-up initialization problems when powering field-programmable gate arrays (FPGAs), digital signal processors (DSPs), or other processors. The controlled voltage ramp of the output also reduces peak in-rush current during start-up, minimizing start-up transients to the input power bus.

To achieve a monotonic start-up, the TPS7A84 error amplifier tracks the voltage ramp of the external soft-start capacitor until the voltage approaches the internal reference. The soft-start ramp time depends on the soft-start

charging current ($I_{NR/SS}$), the soft-start capacitance ($C_{NR/SS}$), and the internal reference ($V_{NR/SS}$). Soft-start ramp time can be calculated with 方程式 1:

$$t_{SS} = (V_{NR/SS} \times C_{NR/SS}) / I_{NR/SS} \tag{1}$$

Note that $I_{NR/SS}$ is provided in the *Electrical Characteristics* table and has a typical value of 6.2 µA.

The noise-reduction capacitor, in conjunction with the noise-reduction resistor, forms a low-pass filter (LPF) that filters out the noise from the reference before being gained up with the error amplifier, thereby reducing the device noise floor. The LPF is a single-pole filter and the cutoff frequency can be calculated with 方程式 2. The typical value of R_{NR} is 250 kΩ. Increasing the $C_{NR/SS}$ capacitor has a greater affect because the output voltage increases when the noise from the reference is gained up even more at higher output voltages. For low-noise applications, a 10-nF to 1-µF $C_{NR/SS}$ is recommended.

$$f_{cutoff} = 1/ (2 \times \pi \times R_{NR} \times C_{NR/SS}) \tag{2}$$

8.1.4 Feed-Forward Capacitor (C_{FF})

Although a feed-forward capacitor (C_{FF}) from the FB pin to the OUT pin is not required to achieve stability, a 10-nF external feed-forward capacitor optimizes the transient, noise, and PSRR performance. A higher capacitance C_{FF} can be used; however, the start-up time is longer and the power-good signal can incorrectly indicate that the output voltage is settled. For a detailed description, see the *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator* application report.

8.1.5 Soft-Start and In-Rush Current

Soft-start refers to the ramp-up characteristic of the output voltage during LDO turn-on after EN and UVLO achieve threshold voltage. The noise-reduction capacitor serves a dual purpose of both governing output noise reduction and programming the soft-start ramp during turn-on.

In-rush current is defined as the current into the LDO at the IN pin during start-up. In-rush current then consists primarily of the sum of load current and the current used to charge the output capacitor. This current is difficult to measure because the input capacitor must be removed, which is not recommended. However, this soft-start current can be estimated by 方程式 3:

$$I_{OUT(t)} = \left[\frac{C_{OUT} \times dV_{OUT}(t)}{dt} \right] + \left[\frac{V_{OUT}(t)}{R_{LOAD}} \right] \tag{3}$$

where:

- $V_{OUT}(t)$ is the instantaneous output voltage of the turn-on ramp
- $dV_{OUT}(t) / dt$ is the slope of the V_{OUT} ramp
- R_{LOAD} is the resistive load impedance

8.1.6 Optimizing Noise and PSRR

The ultra-low noise floor and PSRR of the device can be improved by careful selection of:

- $C_{NR/SS}$ for the low-frequency range
- C_{FF} in the mid-band frequency range
- C_{OUT} for the high-frequency range
- V_{IN} – V_{OUT} for all frequencies, and
- V_{BIAS} at lower input voltages

A larger noise-reduction capacitor improves low-frequency PSRR by filtering any noise coupling from the input into the reference. The feed-forward capacitor can be optimized to place a pole-zero pair near the edge of the loop bandwidth and push out the loop bandwidth, thus improving mid-band PSRR. Larger output capacitors and various output capacitors can be used to improve high-frequency PSRR.

A higher input voltage improves the PSRR by giving the device more headroom to respond to noise on the input; see the 图 6-2 curve. A bias rail also improves the PSRR at lower input voltages because greater headroom is provided for the internal circuits.

The noise-reduction capacitor filters out low-frequency noise from the reference and the feed-forward capacitor reduces output voltage noise by filtering out the mid-band frequency noise. However, a large feed-forward capacitor can create some new issues that are discussed in the *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator* application report.

A large output capacitor reduces high-frequency output voltage noise. Additionally, a bias rail or higher input voltage improves the noise because greater headroom is provided for the internal circuits.

表 8-1 lists the output voltage noise for the 10-Hz to 100-kHz band at a 5.0-V output for a variety of conditions with an input voltage of 5.4 V, an R_1 of 12.1 kΩ, and a load current of 3 A. The 5.0-V output is chosen because this output is the worst-case condition for output voltage noise.

表 8-1. Output Noise Voltage at a 5.0-V Output

OUTPUT VOLTAGE NOISE (μV_{RMS})	$C_{NR/SS}$ (nF)	C_{FF} (nF)	C_{OUT} (μF)
11.7	10	10	47 || 10 || 10
7.7	100	10	47 || 10 || 10
6	100	100	47 || 10 || 10
7.4	100	10	1000
5.8	100	100	1000

8.1.7 Charge Pump Noise

The device internal charge pump generates a minimal amount of noise, as shown in 图 8-1.

Using a bias rail minimizes the internal charge pump noise when the internal voltage is clamped, thereby reducing the overall output noise floor.

The high-frequency components of the output voltage noise density curve are filtered out in most applications by using 10-nF to 100-nF bypass capacitors close to the load. Using a ferrite bead between the LDO output and the load input capacitors forms a pi-filter, further reducing the high-frequency noise contribution.

图 8-1. Charge Pump Noise

Product Folder Links: *TPS7A84*
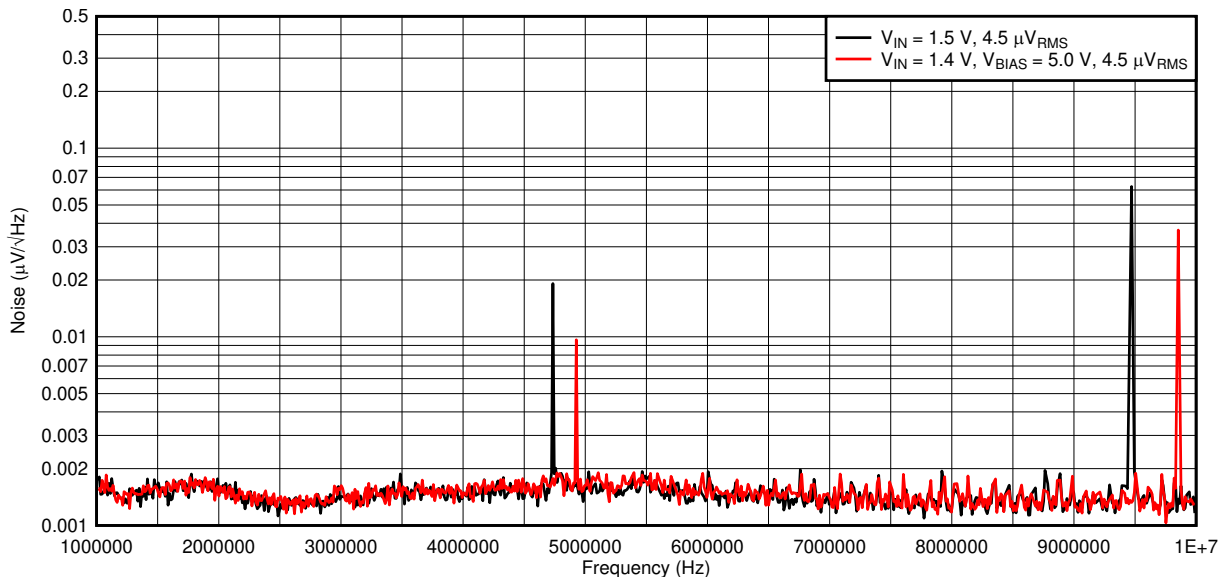
8.1.8 ANY-OUT Programmable Output Voltage

The TPS7A84 can use either external resistors or the internally-matched ANY-OUT feedback resistor network to set output voltage. The ANY-OUT resistors are accessible via pin 2 and pins 5 to 11 and are used to program the regulated output voltage. Each pin is can be connected to ground (active) or left open (floating), or connected to SNS. ANY-OUT programming is set by 方程式 4 as the sum of the internal reference voltage ($V_{NR/SS} = 0.8$ V) plus the accumulated sum of the respective voltages assigned to each active pin; that is, 50mV (pin 5), 100mV (pin 6), 200mV (pin 7), 400mV (pin 9), 800mV (pin 10), or 1.6V (pin 11). 表 8-2 summarizes these voltage values associated with each active pin setting for reference. By leaving all program pins open or floating, the output is thereby programmed to the minimum possible output voltage equal to V_{FB}.

$$V_{OUT} = V_{NR/SS} + (\Sigma \text{ ANY-OUT Pins to Ground})$$

(4)

表 8-2. ANY-OUT Programmable Output Voltage

ANY-OUT PROGRAM PINS (Active Low)	ADDITIVE OUTPUT VOLTAGE LEVEL
Pin 5 (50mV)	50 mV
Pin 6 (100mV)	100 mV
Pin 7 (200mV)	200 mV
Pin 9 (400mV)	400 mV
Pin 10 (800mV)	800 mV
Pin 11 (1.6V)	1.6 V

表 8-3 provides a full list of target output voltages and corresponding pin settings when the ANY-OUT pins are only tied to ground or left floating. The voltage setting pins have a binary weight; therefore, the output voltage can be programmed to any value from 0.8 V to 3.95 V in 50-mV steps when tying these pins to ground. There are several alternative ways to set the output voltage. The program pins can be driven using external general-purpose input/output pins (GPIOs), manually connected using 0-Ω resistors (or left open), or hardwired by the given layout of the printed circuit board (PCB) to set the ANY-OUT voltage. As with the adjustable operation, the output voltage is set according to 方程式 5 except that R_1 and R_2 are internally integrated and matched for higher accuracy. Tying any of the ANY-OUT pins to SNS can increase the resolution of the internal feedback network by lowering the value of R_1. See the *Increasing ANY-OUT Resolution for LILO Conditions* section for additional information.

$$V_{OUT} = V_{NR/SS} \times (1 + R_1 / R_2)$$

(5)

Note

For output voltages greater than 3.95 V, use a traditional adjustable configuration (see the *Adjustable Operation* section).

表 8-3. **User-Configurable Output Voltage Settings**

V_{OUT(NOM)} (V)	50mV	100mV	200mV	400mV	800mV	1.6V	V_{OUT(NOM)} (V)	50mV	100mV	200mV	400mV	800mV	1.6V
0.80	Open	Open	Open	Open	Open	Open	2.40	Open	Open	Open	Open	Open	GND
0.85	GND	Open	Open	Open	Open	Open	2.45	GND	Open	Open	Open	Open	GND
0.90	Open	GND	Open	Open	Open	Open	2.50	Open	GND	Open	Open	Open	GND
0.95	GND	GND	Open	Open	Open	Open	2.55	GND	GND	Open	Open	Open	GND
1.00	Open	Open	GND	Open	Open	Open	2.60	Open	Open	GND	Open	Open	GND
1.05	GND	Open	GND	Open	Open	Open	2.65	GND	Open	GND	Open	Open	GND
1.10	Open	GND	GND	Open	Open	Open	2.70	Open	GND	GND	Open	Open	GND
1.15	GND	GND	GND	Open	Open	Open	2.75	GND	GND	GND	Open	Open	GND
1.20	Open	Open	Open	GND	Open	Open	2.80	Open	Open	Open	GND	Open	GND
1.25	GND	Open	Open	GND	Open	Open	2.85	GND	Open	Open	GND	Open	GND
1.30	Open	GND	Open	GND	Open	Open	2.90	Open	GND	Open	GND	Open	GND
1.35	GND	GND	Open	GND	Open	Open	2.95	GND	GND	Open	GND	Open	GND
1.40	Open	Open	GND	GND	Open	Open	3.00	Open	Open	GND	GND	Open	GND
1.45	GND	Open	GND	GND	Open	Open	3.05	GND	Open	GND	GND	Open	GND
1.50	Open	GND	GND	GND	Open	Open	3.10	Open	GND	GND	GND	Open	GND
1.55	GND	GND	GND	GND	Open	Open	3.15	GND	GND	GND	GND	Open	GND
1.60	Open	Open	Open	Open	GND	Open	3.20	Open	Open	Open	Open	GND	GND
1.65	GND	Open	Open	Open	GND	Open	3.25	GND	Open	Open	Open	GND	GND
1.70	Open	GND	Open	Open	GND	Open	3.30	Open	GND	Open	Open	GND	GND
1.75	GND	GND	Open	Open	GND	Open	3.35	GND	GND	Open	Open	GND	GND
1.80	Open	Open	GND	Open	GND	Open	3.40	Open	Open	GND	Open	GND	GND
1.85	GND	Open	GND	Open	GND	Open	3.45	GND	Open	GND	Open	GND	GND
1.90	Open	GND	GND	Open	GND	Open	3.50	Open	GND	GND	Open	GND	GND
1.95	GND	GND	GND	Open	GND	Open	3.55	GND	GND	GND	Open	GND	GND
2.00	Open	Open	Open	GND	GND	Open	3.60	Open	Open	Open	GND	GND	GND
2.05	GND	Open	Open	GND	GND	Open	3.65	GND	Open	Open	GND	GND	GND
2.10	Open	GND	Open	GND	GND	Open	3.70	Open	GND	Open	GND	GND	GND
2.15	GND	GND	Open	GND	GND	Open	3.75	GND	GND	Open	GND	GND	GND
2.20	Open	Open	GND	GND	GND	Open	3.80	Open	Open	GND	GND	GND	GND
2.25	GND	Open	GND	GND	GND	Open	3.85	GND	Open	GND	GND	GND	GND
2.30	Open	GND	GND	GND	GND	Open	3.90	Open	GND	GND	GND	GND	GND
2.35	GND	GND	GND	GND	GND	Open	3.95	GND	GND	GND	GND	GND	GND

Product Folder Links: *TPS7A84*

8.1.9 ANY-OUT Operation

Considering the use of the ANY-OUT internal network (where the unit resistance of 1R is equal to 6.05 kΩ) the output voltage is set by grounding the appropriate control pins, as shown in 图 8-2. When grounded, all control pins add a specific voltage on top of the internal reference voltage ($V_{NR/SS}$ = 0.8 V). The output voltage can be calculated by 方程式 6 and 方程式 7. 图 8-2 and 图 8-3 show a 0.9-V output voltage, respectively, that provide an example of the circuit usage with and without bias voltage.
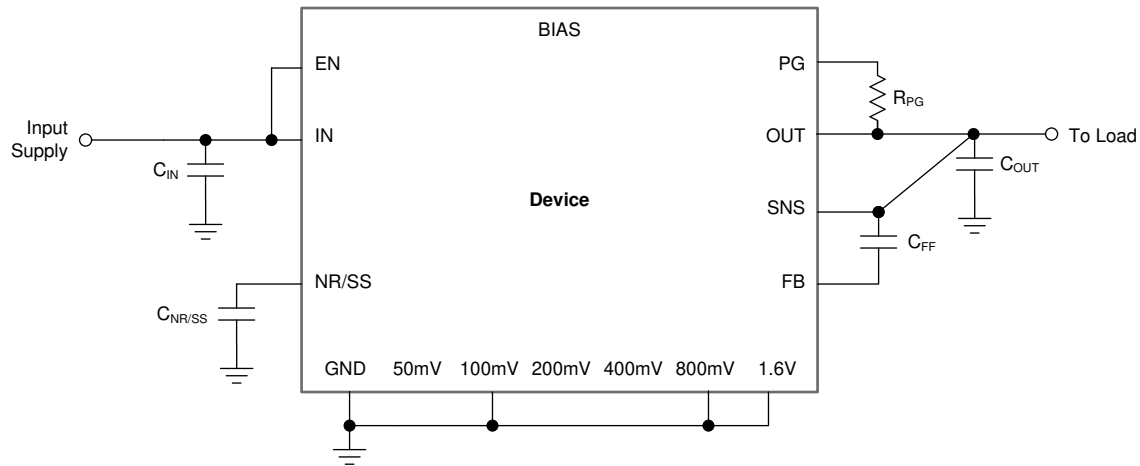
图 8-2. ANY-OUT Configuration Circuit (3.3-V Output, No External Bias)

$$V_{OUT(nom)} = V_{NR/SS} + 1.6\ V + 0.8\ V + 0.1\ V = 0.8\ V + 1.6\ V + 0.8\ V + 0.1\ V = 3.3\ V \tag{6}$$
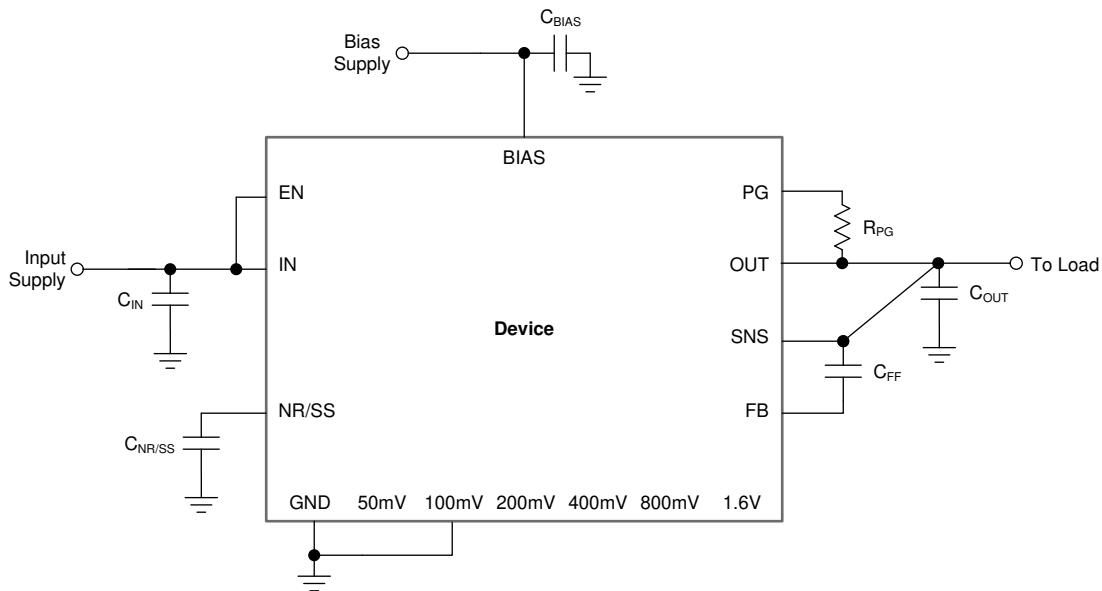
图 8-3. ANY-OUT Configuration Circuit (0.9-V Output with Bias)

$$V_{OUT(nom)} = V_{NR/SS} + 0.1\ V = 0.8\ V + 0.1\ V = 0.9\ V \tag{7}$$

8.1.10 Increasing ANY-OUT Resolution for LILO Conditions

As with the adjustable operation, the output voltage is set according to 方程式 5, except that R_1 and R_2 are internally integrated and matched for higher accuracy. Tying any of the ANY-OUT pins to SNS can increase the resolution of the internal feedback network by lowering the value of R_1. One of the more useful pin combinations is to tie the 800mV pin to SNS, which reduces the resolution by 50% to 25 mV but limits the range. The new

ANY-OUT ranges are 0.8 V to 1.175 V and 1.6 V to 1.975 V. The new additive output voltage levels are listed in 表 8-4.

表 8-4. ANY-OUT Programmable Output Voltage with 800mV Tied to SNS

ANY-OUT PROGRAM PINS (Active Low)	ADDITIVE OUTPUT VOLTAGE LEVEL
Pin 5 (50mV)	25 mV
Pin 6 (100mV)	50 mV
Pin 7 (200mV)	100 mV
Pin 9 (400mV)	200 mV
Pin 11 (1.6V)	800 V

8.1.11 Current Sharing

Current sharing is possible through the use of external operational amplifiers. For more details, see the *6A Current-Sharing Dual LDO* design guide.

8.1.12 Adjustable Operation

The TPS7A84 can be used either with the internal ANY-OUT network or by using external resistors. Using the ANY-OUT network allows the TPS7A84 to be programmed from 0.8 V to 3.95 V. To extend this output voltage range to 5.0 V, external resistors must be used. This configuration is referred to as the adjustable configuration of the TPS7A84 throughout this document. Regardless whether the internal resistor network or whether external resistors are used, the output voltage is set by two resistors, as shown in 图 8-4. Using the internal resistor ensures a 1% accuracy and minimizes the number of external components.
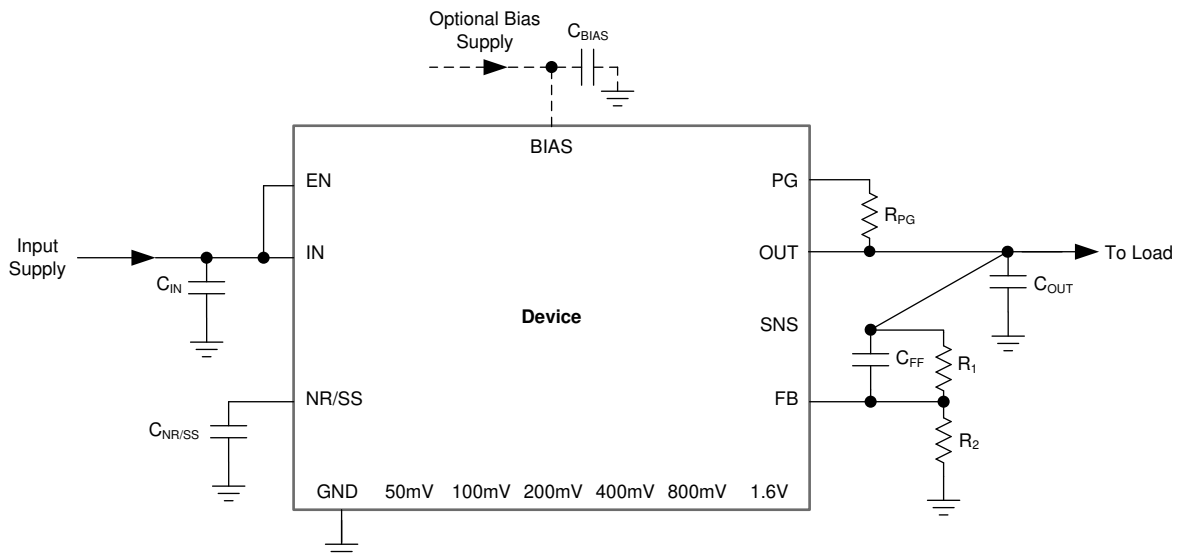
图 8-4. Adjustable Operation

R_1 and R_2 can be calculated for any output voltage range using 方程式 8. This resistive network must provide a current equal to or greater than 5 μA for dc accuracy. Using an R_1 of 12.1 kΩ is recommended to optimize the noise and PSRR.

$$V_{OUT} = V_{NR/SS} \times (1 + R_1 / R_2) \tag{8}$$

表 8-5 shows the resistor combinations required to achieve several common rails using standard 1%-tolerance resistors.

表 8-5. Recommended Feedback-Resistor Values[1]

TARGETED OUTPUT VOLTAGE (V)	FEEDBACK RESISTOR VALUES		CALCULATED OUTPUT VOLTAGE (V)
	R_1 (kΩ)	R_2 (kΩ)	
0.9	12.4	100	0.899
0.95	12.4	66.5	0.949
1.00	12.4	49.9	0.999
1.10	12.4	33.2	1.099
1.20	12.4	24.9	1.198
1.50	12.4	14.3	1.494
1.80	12.4	10	1.798
1.90	12.1	8.87	1.89
2.50	12.4	5.9	2.48
2.85	12.1	4.75	2.838
3.00	12.1	4.42	2.990
3.30	11.8	3.74	3.324
3.60	12.1	3.48	3.582
4.5	11.8	2.55	4.502
5.00	12.4	2.37	4.985

(1) R_1 is connected from OUT to FB; R_2 is connected from FB to GND.

8.1.13 Sequencing Requirements

Supply and enable sequencing is only required when the bias rail is present. The start-up is always monotonic, independent of the sequencing requirements. Under these conditions the following requirements apply:

* V_{BIAS} and V_{IN} can be sequenced in any order, as long as V_{EN} is tied to V_{IN} or established after V_{IN}, as shown in 图 8-5.
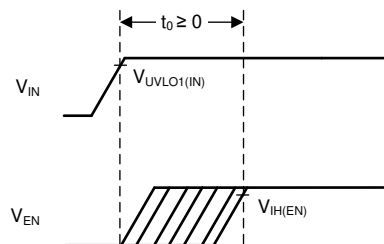

图 8-5. Sequencing Diagram

Two typical application circuits for implementing the sequencing requirements are detailed in the *Sequencing with a Power-Good DC-DC Converter Pin* and *Sequencing with a Microcontroller (MCU)* sections.

8.1.13.1 Sequencing with a Power-Good DC-DC Converter Pin

When a dc-dc converter is used to power the device and the PG of the dc-dc converter is used to enable the device, pull PGup to V_{IN}, as shown in 图 8-6.
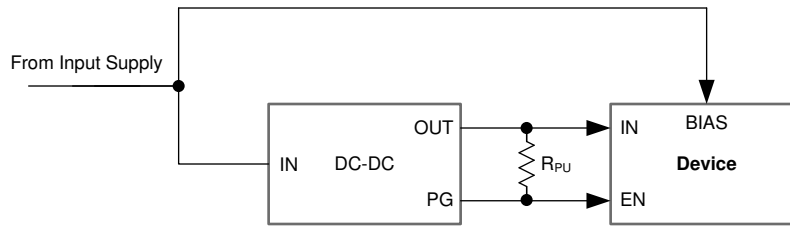
图 8-6. Sequencing with a DC-DC Converter and PG

8.1.13.2 Sequencing with a Microcontroller (MCU)

If a push-pull output stage is used to provide the enable signal to the device and the enable signal can possibly come before V_{IN} when a bias is present (such as with an MCU), convert the enable signal to an open-drain signal as shown in 图 8-7. Using an open-drain signal ensures that if the signal arrives before V_{IN}, then the enable voltage does not violate the sequencing requirement.
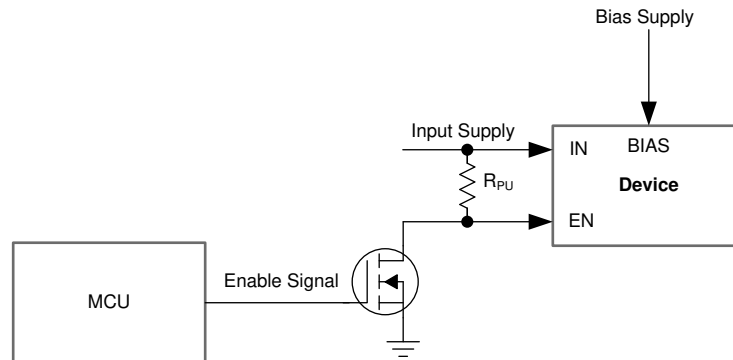
图 8-7. Push-Pull Enable to Open-Drain Enable

8.1.14 Power-Good Operation

To ensure proper operation of the power-good circuit, the pullup resistor value must be between 10 kΩ and 100 kΩ. The lower limit of 10 kΩ results from the maximum pulldown strength of the power-good transistor, and the upper limit of 100 kΩ results from the maximum leakage current at the power-good node. If the pullup resistor is outside of this range, then the power-good signal may not read a valid digital logic level.

Using a large C_{FF} with a small $C_{NR/SS}$ causes the power-good signal to incorrectly indicate that the output voltage has settled during turn-on. The C_{FF} time constant must be greater than the soft-start time constant to ensure proper operation of the PG during start-up. For a detailed description, see the *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator* application report.

The state of PG is only valid when the device operates above the minimum supply voltage. During short UVLO events and at light loads, power-good does not assert because the output voltage is sustained by the output capacitance.

8.1.15 Undervoltage Lockout (UVLO) Operation

The UVLO circuit ensures that the device stays disabled before its input or bias supplies reach the minimum operational voltage range, and ensures that the device shuts down when the input supply or bias supply collapse.

The UVLO circuit has a minimum response time of several microseconds to fully assert. During this time, a downward line transient below approximately 0.8 V causes the UVLO to assert for a short time; however, the UVLO circuit does not have enough stored energy to fully discharge the internal circuits inside of the device. When the UVLO circuit does not fully discharge, the internal circuits of the output are not fully disabled.

The effect of the downward line transient can be mitigated by either using a larger input capacitor to limit the fall time of the input supply when operating near the minimum V_{IN}, or by using a bias rail.

图 8-8 shows the UVLO circuit response to various input voltage events. The diagram can be separated into the following parts:

- Region A: The device does not turn on until the input reaches the UVLO rising threshold.
- Region B: Normal operation with a regulated output
- Region C: Brownout event above the UVLO falling threshold (UVLO rising threshold – UVLO hysteresis). The output may fall out of regulation but the device is still enabled.
- Region D: Normal operation with a regulated output
- Region E: Brownout event below the UVLO falling threshold. The device is disabled in most cases and the output falls because of the load and active discharge circuit. The device is reenabled when the UVLO rising threshold is reached by the input voltage and a normal start-up then follows.
- Region F: Normal operation followed by the input falling to the UVLO falling threshold.
- Region G: The device is disabled when the input voltage falls below the UVLO falling threshold to 0 V. The output falls because of the load and active discharge circuit.
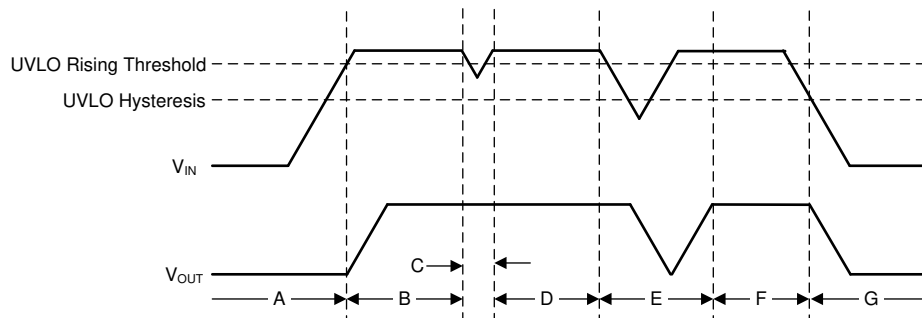
图 8-8. **Typical UVLO Operation**

8.1.16 Dropout Voltage (V_DO)

Generally speaking, the dropout voltage often refers to the minimum voltage difference between the input and output voltage ($V_{DO} = V_{IN} - V_{OUT}$) that is required for regulation. When V_{IN} drops below the required V_{DO} for the given load current, the device functions as a resistive switch and does not regulate output voltage. Dropout voltage is proportional to the output current because the device is operating as a resistive switch; see the 图 6-22, 图 6-23, and 图 6-24 curves.

Dropout voltage is affected by the drive strength for the gate of the pass element, which is nonlinear with respect to V_{IN} on this device because of the internal charge pump. The charge pump causes a higher dropout voltage at lower input voltages when a bias rail is not used, as illustrated in the 图 6-20 curve.

For this device, dropout voltage increases exponentially when the input voltage nears its maximum operating voltage because the charge pump is internally clamped to 8.0 V; see the 图 6-20 and 图 6-21 curves.

8.1.17 Behavior when Transitioning from Dropout into Regulation

Some applications may have transients that place the device into dropout, especially because this device is a high-current linear regulator. A typical application with these conditions requires setting $V_{IN} \leqslant V_{DO}$ in order to keep the device junction temperature within its specified operating range. A load transient or line transient in these conditions can place the device into dropout, such as a load transient from 1 A to 4 A at 1A/μs when operating with a V_{IN} of 5.4- V and a V_{OUT} of 5.0 V.

The load transient saturates the error amplifier output stage when the pass element is fully driven on, thus making the pass element function like a resistor from V_{IN} to V_{OUT}. The error amplifier response time to this load transient (I_{OUT} = 4 A to 1 A at 1 A/μs) is limited because the error amplifier must first recover from saturation and then place the pass element back into active mode. During the recovery from the load transient, V_{OUT} overshoots because the pass element is functioning as a resistor from V_{IN} to V_{OUT}. If operating under these conditions, apply a higher dc load or increase the output capacitance to reduce the overshoot because these solutions provide a path to dissipate the excess charge.

8.1.18 Load Transient Response

The load-step transient response is the output voltage response by the LDO to a step in load current, whereby output voltage regulation is maintained; see the 图 6-16 curve. There are two key transitions during a load transient response: the transition from a light to a heavy load and the transition from a heavy to a light load. The regions shown in 图 8-9 are broken down in this section. Regions A, E, and H are where the output voltage is in steady-state.

During transitions from a light load to a heavy load, the:

- Initial voltage dip is a result of the depletion of the output capacitor charge and parasitic impedance to the output capacitor (region B).
- Recovery from the dip results from the LDO increasing its sourcing current, and leads to output voltage regulation (region C).

During transitions from a heavy load to a light load, the:

- Initial voltage rise results from the LDO sourcing a large current, and leads to the output capacitor charge to increase (region F).
- Recovery from the rise results from the LDO decreasing its sourcing current in combination with the load discharging the output capacitor (region G).

Transitions between current levels changes the internal power dissipation because the TPS7A84 is a high-current device (region D). The change in power dissipation changes the die temperature during these transitions, and leads to a slightly different voltage level. This different output voltage level shows up in the various load transient responses; see the 图 6-16 curve.

A larger output capacitance reduces the peaks during a load transient but slows down the response time of the device. A larger dc load also reduces the peaks because the amplitude of the transition is lowered and a higher current discharge path is provided for the output capacitor; see the 图 6-18 curve.
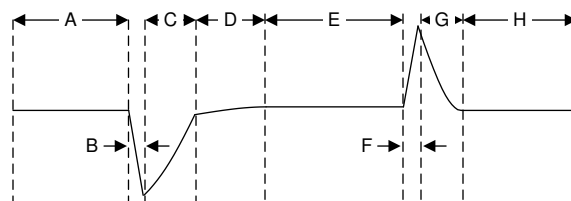
图 8-9. Load Transient Waveform

8.1.19 Negatively-Biased Output

The device does not start or operate as expected if the output voltage is pulled below ground. This issue commonly occurs when powering a split-rail system where the negative rail is established before the device is enabled. Several application solutions are:

- Enable the device before the negative regulator and disable the device after the negative regulator.
- Delaying the EN voltage with respect to the IN voltage allows the internal pulldown resistor to discharge any voltage at OUT. If the discharge circuit is not strong enough to keep the output voltage at ground, then use an external pulldown resistor.
- Place a zener diode from IN to OUT to provide a small positive dc bias on the output when the input is supplied to the device, as shown in 图 8-10.
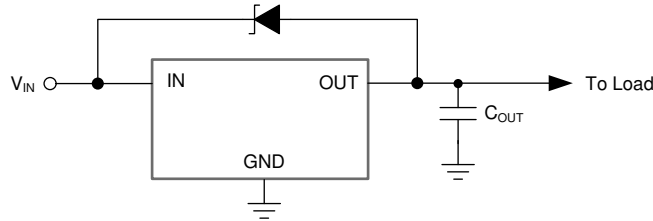
图 8-10. Zener Diode Placed from IN to OUT

- Use a PFET to isolate the output of the device from the load causing the negative bias when the device is off, as shown in 图 8-11.
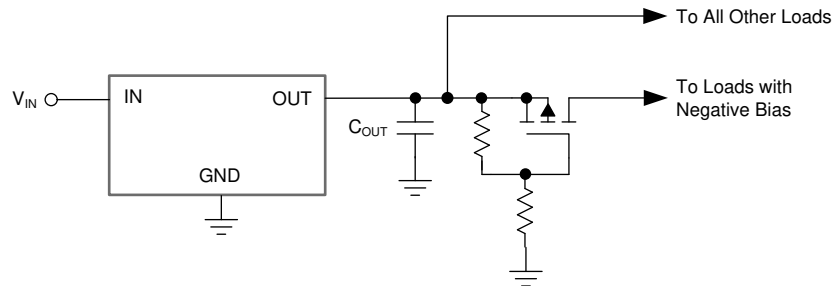
图 8-11. PFET to Isolate the Output from the Load

8.1.20 Reverse Current Protection

As with most LDOs, this device can be damaged by excessive reverse current.

Conditions where excessive reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of $V_{OUT} > V_{IN} + 0.3$ V:

- If the device has a large C_{OUT}, then the input supply collapses quickly and the load current becomes very small
- The output is biased when the input supply is not established
- The output is biased above the input supply

Product Folder Links: *TPS7A84*

If an excessive reverse current flow is expected in the application, then external protection must be used to protect the device. 图 8-12 shows one approach of protecting the device.

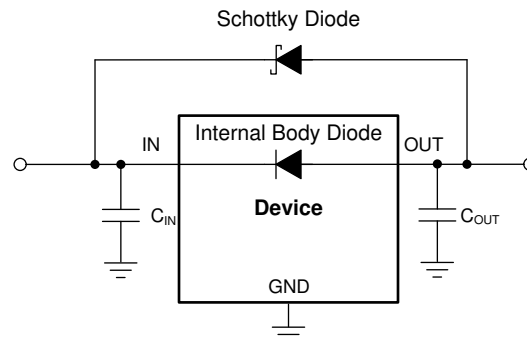

图 8-12. Example Circuit for Reverse Current Protection Using a Schottky Diode

8.1.21 Power Dissipation (P_D)

Circuit reliability demands that proper consideration be given to device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must be as free as possible of other heat-generating devices that cause added thermal stresses.

As a first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. P_D can be calculated using 方程式 9:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \tag{9}$$

An important note is that power dissipation can be minimized, and thus greater efficiency achieved, by proper selection of the system voltage rails. Proper selection allows the minimum input-to-output voltage differential to be obtained. The low dropout of the TPS7A84 allows for maximum efficiency across a wide range of output voltages.

The primary heat conduction path for the package is through the thermal pad to the PCB. Solder the thermal pad to a copper pad area under the device. This pad area contains an array of plated vias that conduct heat to any inner plane areas or to a bottom-side copper plane.

The maximum power dissipation determines the maximum allowable junction temperature (T_J) for the device. Power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air (T_A), according to 方程式 10. The equation is rearranged for output current in 方程式 11.

$$T_J = T_A + (R_{\theta JA} \times P_D) \tag{10}$$

$$I_{OUT} = (T_J - T_A) / [R_{\theta JA} \times (V_{IN} - V_{OUT})] \tag{11}$$

Unfortunately, this thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The $R_{\theta JA}$ recorded in the *Electrical Characteristics* table is determined by the JEDEC standard, PCB, and copper-spreading area, and is only used as a relative measure of package thermal performance. For a well-designed thermal layout, $R_{\theta JA}$ is actually the sum of the VQFN package junction-to-case (bottom) thermal resistance ($R_{\theta JCbot}$) plus the thermal resistance contribution by the PCB copper.

8.1.22 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the LDO when in-circuit on a typical PCB board application. These metrics are not strictly speaking thermal resistances, but rather offer practical and relative means of estimating junction temperatures. These psi metrics are determined to be significantly independent of the copper-spreading area. The key thermal metrics (Ψ_{JT} and Ψ_{JB}) are given in the *Electrical Characteristics* table and are used in accordance with 方程式 12.

$$\Psi_{JT}: T_J = T_T + \Psi_{JT} \times P_D$$
$$\Psi_{JB}: T_J = T_B + \Psi_{JB} \times P_D$$

(12)

where:

- P_D is the power dissipated as explained in 方程式 9
- T_T is the temperature at the center-top of the device package, and
- T_B is the PCB surface temperature measured 1 mm from the device package and centered on the package edge

8.1.23 Recommended Area for Continuous Operation (RACO)

The operational area of an LDO is limited by the dropout voltage, output current, junction temperature, and input voltage. The recommended area for continuous operation for a linear regulator can be separated into the following parts, and is shown in 图 8-13:

- Limited by dropout: Dropout voltage limits the minimum differential voltage between the input and the output ($V_{IN} - V_{OUT}$) at a given output current level.
- Limited by rated output current: The rated output current limits the maximum recommended output current level. Exceeding this rating causes the device to fall out of specification.
- Limited by thermals: The shape of the slope is given by 方程式 11. The slope is nonlinear because the junction temperature of the LDO is controlled by the power dissipation across the LDO; therefore, when $V_{IN} - V_{OUT}$ increases, the output current must decrease in order to ensure that the rated junction temperature of the device is not exceeded. Exceeding this rating can cause the device to fall out of specifications and reduces long-term reliability.
- Limited by V_{IN} range: The rated input voltage range governs both the minimum and maximum of $V_{IN} - V_{OUT}$.
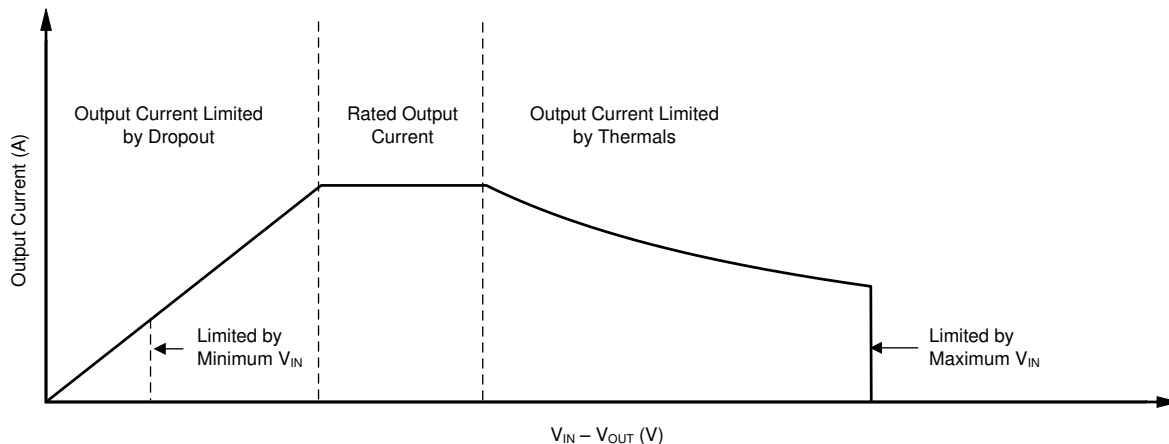
图 8-13. Continuous Operation Slope Region Description

Product Folder Links: *TPS7A84*

图 8-14 to 图 8-19 show the recommended area of operation curves for this device on a JEDEC-standard high-K board with a $R_{\theta JA}$ = 35.4°C/W, as given in the *Electrical Characteristics* table.

图 **8-14. Recommended Area for Continuous Operation for V$_{OUT}$ = 0.9 V With Bias**
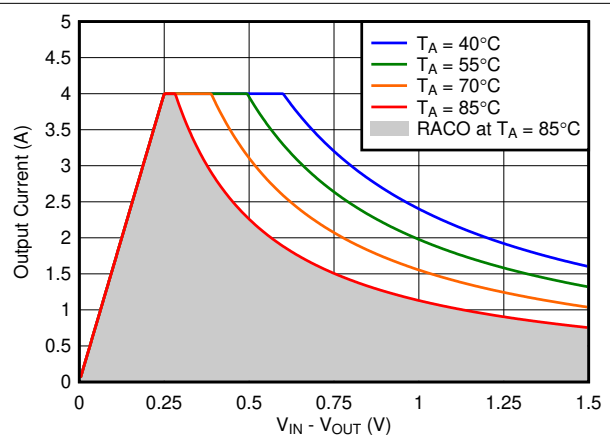
图 **8-15. Recommended Area for Continuous Operation for V$_{OUT}$ = 1.2 V With Bias**

图 **8-16. Recommended Area for Continuous Operation for V$_{OUT}$ = 1.8 V**

图 **8-17. Recommended Area for Continuous Operation for V$_{OUT}$ = 2.5 V**

图 **8-18. Recommended Area for Continuous Operation for V$_{OUT}$ = 3.3 V**

图 **8-19. Recommended Area for Continuous Operation for V$_{OUT}$ = 5.0 V**

Product Folder Links: *TPS7A84*

8.2 Typical Applications

8.2.1 Low-Input, Low-Output (LILO) Voltage Conditions

This section discusses the implementation of the TPS7A84 using the ANY-OUT configuration to regulate a 3.0-A load requiring good PSRR at high frequency with low-noise 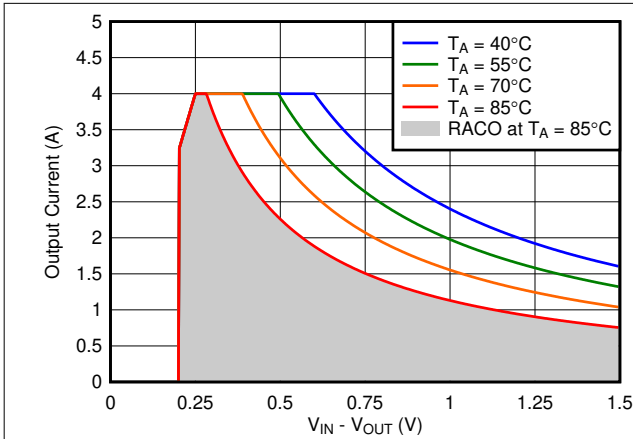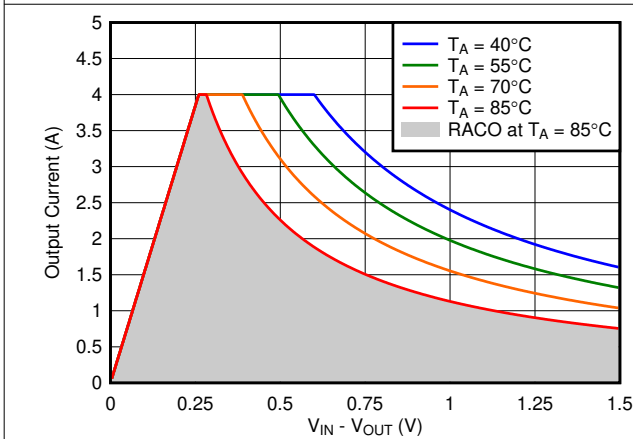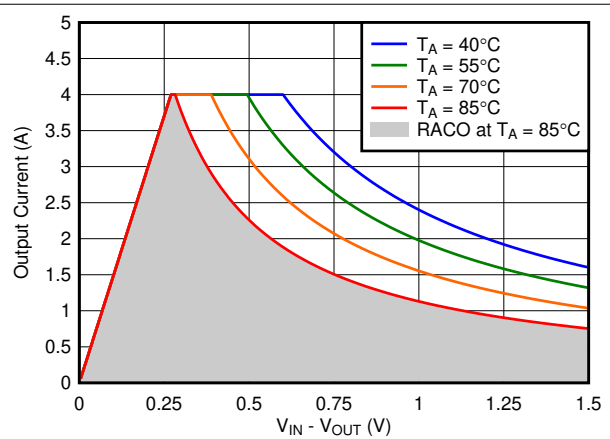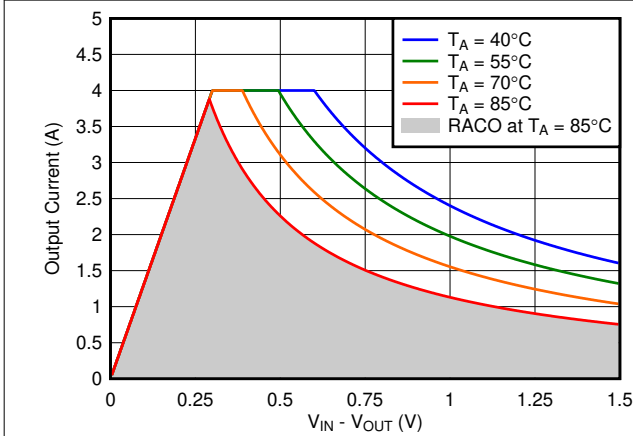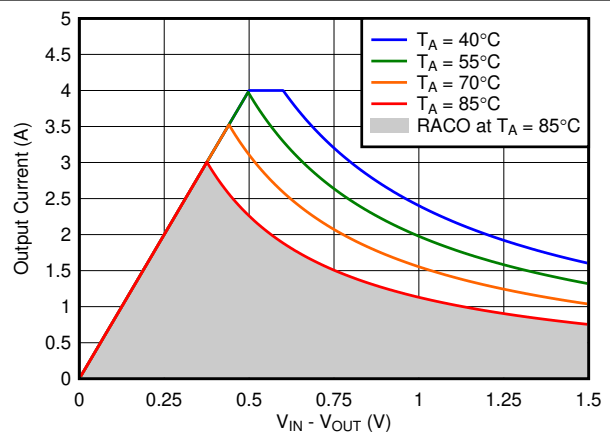at 0.9 V using a 1.3-V input voltage and a 5.0-V bias supply. The schematic for this typical application circuit is provided in 图 8-20.

图 8-20. Typical Application

8.2.1.1 Design Requirements

For this design example, use the parameters listed in 表 8-6 as the input parameters.

表 8-6. Design Parameters

PARAMETER	DESIGN REQUIREMENT
Input voltage	1.3 V, ±3%, provided by the dc-dc converter switching at 500 kHz
Bias voltage	5.0 V, ±5%
Output voltage	0.9 V, ±1%
Output current	3.0 A (maximum), 100 mA (minimum)
RMS noise, 10 Hz to 100 kHz	< 10 μV_{RMS}
PSRR at 500 kHz	> 40 dB
Start-up time	< 25 ms

8.2.1.2 Detailed Design Procedure

At 3.0 A, the dropout of the TPS7A84 has 180-mV maximum dropout over temperature, thus a 400-mV headroom is sufficient for operation over both input and output voltage accuracy. The bias rail is provided for better performance for the LILO conditions. The PSRR is greater than 40 dB in these conditions, as per the 图 6-1 curve. Noise is less than 10 μV_{RMS}, as per the 图 6-8 curve.

The ANY-OUT internal resistor network is also used for maximum accuracy.

To achieve 0.9 V on the output, the 100mV pin is grounded. The voltage value of 100 mV is added to the 0.8-V internal reference voltage for $V_{OUT(nom)}$ equal to 0.9 V, as described in 方程式 13.

$$V_{OUT(nom)} = V_{NR/SS} + 0.1 \text{ V} = 0.8 \text{ V} + 0.1 \text{ V} = 0.9 \text{ V} \tag{13}$$

Product Folder Links: *TPS7A84*

Input and output capacitors are selected in accordance with the *Recommended Capacitor Types* section. Ceramic capacitances of 47 µF for the input and one 47-µF capacitor in parallel with two 10-µF capacitors for the output are selected.

To satisfy the required start-up time and still maintain low-noise performance, a 100-nF $C_{NR/SS}$ is selected. This value is calculated with 方程式 14.

$$t_{SS} = (V_{NR/SS} \times C_{NR/SS}) / I_{NR/SS} \tag{14}$$

At the 3.0-A maximum load, the internal power dissipation is 1.2 W and corresponds to a 42.48°C junction temperature rise for the RGR package on a standard JEDEC board. With an 55°C maximum ambient temperature, the junction temperature is at 97.5°C. To further minimize noise, a feed-forward capacitance (C_{FF}) of 10 nF is selected.

8.2.1.3 Application Curves

图 8-21. Output Load Transient Response

图 8-22. Output Start-Up Response
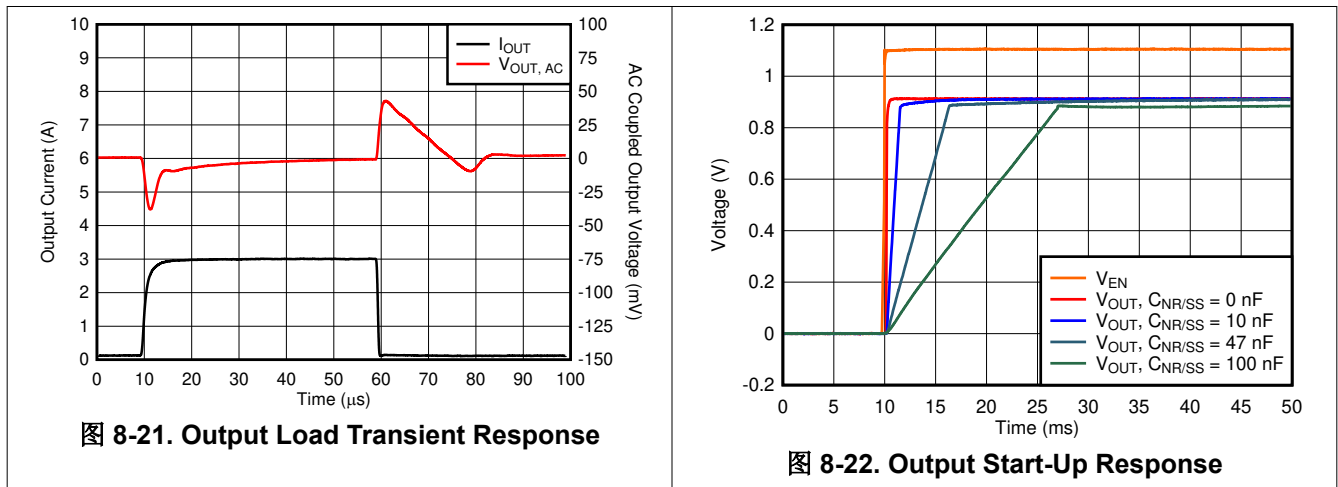
8.2.2 Typical Application for a 5.0-V Rail

This section discusses the implementation of the TPS7A84 using an adjustable feedback network to regulate a 3-A load requiring good PSRR at high frequency with low-noise at an output voltage of 5.0 V. The schematic for this typical application circuit is provided in 图 8-23.

图 8-23. Typical Application

Product Folder Links: *TPS7A84*
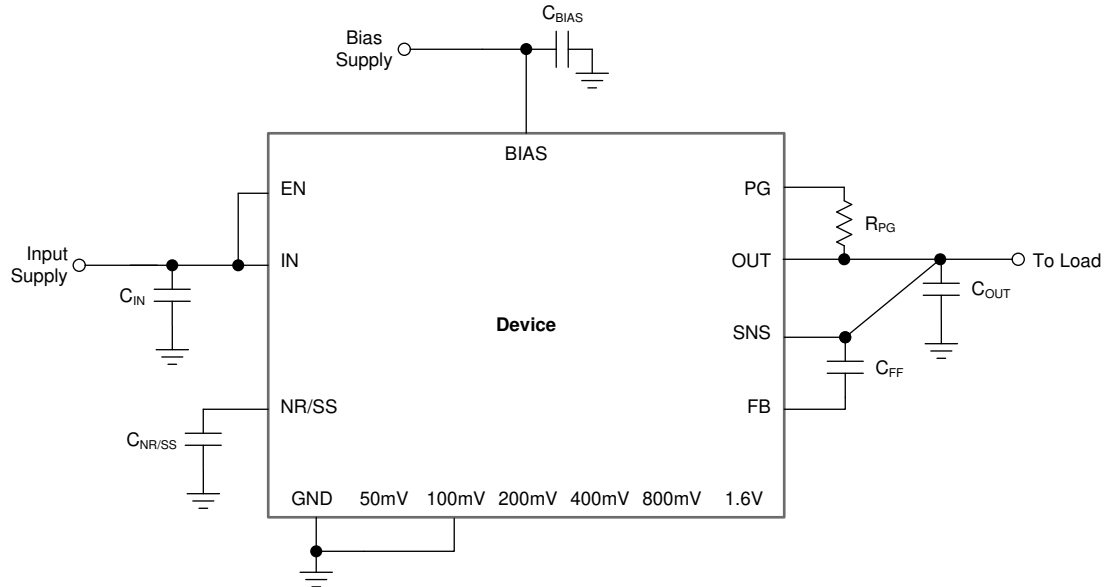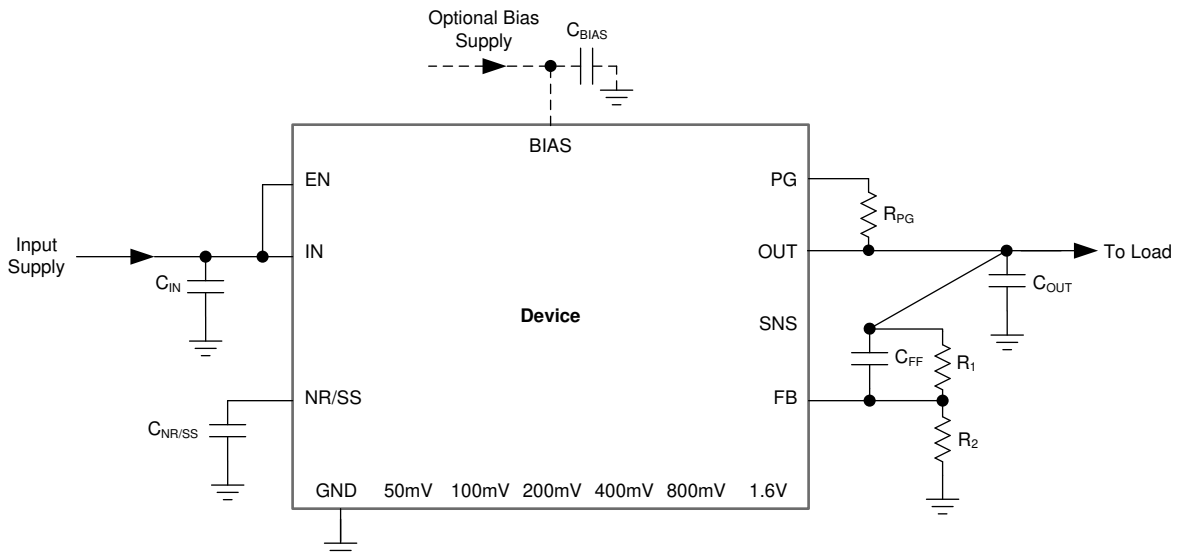
8.2.2.1 Design Requirements

For this design example, use the parameters listed in 表 8-6 as the input parameters.

表 8-7. Design Parameters

PARAMETER	DESIGN REQUIREMENT
Input voltage	5.50 V, ±1%, provided by the dc-dc converter switching at 500 kHz
Bias voltage	Not used because $V_{OUT} \geqslant 2.20$ V
Output voltage	5.0 V, ±1%
Output current	3.0 A (maximum), 10 mA (minimum)
RMS noise, 10 Hz to 100 kHz	< 10 μV_{RMS}
PSRR at 500 kHz	> 40 dB
Start-up time	< 25 ms

8.2.2.2 Detailed Design Procedure

At 3.0 A and 5.0 V_{OUT}, the dropout of the TPS7A84 has a 340-mV maximum dropout over temperature, thus a 500-mV headroom is sufficient for operation over both input and output voltage accuracy. At full load and high temperature on some devices, the TPS7A84 can enter dropout if both the input and output supply are beyond the edges of their accuracy specification.

For a 5.0-V output. use external adjustable resistors. See the resistor values in listed 表 8-5 for choosing resistors for a 5.0-V output.

Input and output capacitors are selected in accordance with the *Recommended Capacitor Types* section. Ceramic capacitances of 47 μF for the input and one 47-μF capacitor in parallel with two 10-μF capacitors for the output are selected.

To satisfy the required start-up time and still maintain low noise performance, a 100-nF $C_{NR/SS}$ is selected. This value is calculated with 方程式 14.

$$t_{SS} = (V_{NR/SS} \times C_{NR/SS}) / I_{NR/SS} \tag{15}$$

At the 3.0-A maximum load, the internal power dissipation is 1.5 W and corresponds to a 53.1°C junction temperature rise for the RGR package on a standard JEDEC board. With an 55°C maximum ambient temperature, the junction temperature is at 108.1°C. To further minimize noise, a feed-forward capacitance (C_{FF}) of 10 nF is selected.

8.2.2.3 Application Curves

图 8-24. PSRR vs Frequency and I_{OUT} for V_{OUT} = 5.0 V

图 8-25. PSRR vs Frequency and V_{IN} for V_{OUT} = 5.0 V at I_{OUT} = 3.0 A

Product Folder Links: *TPS7A84*
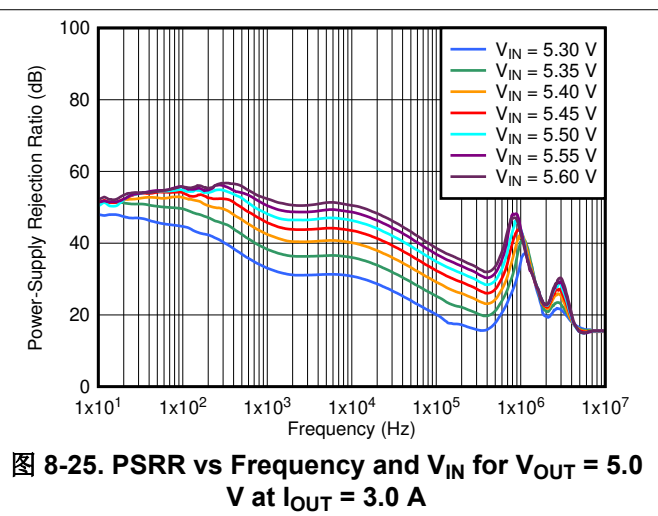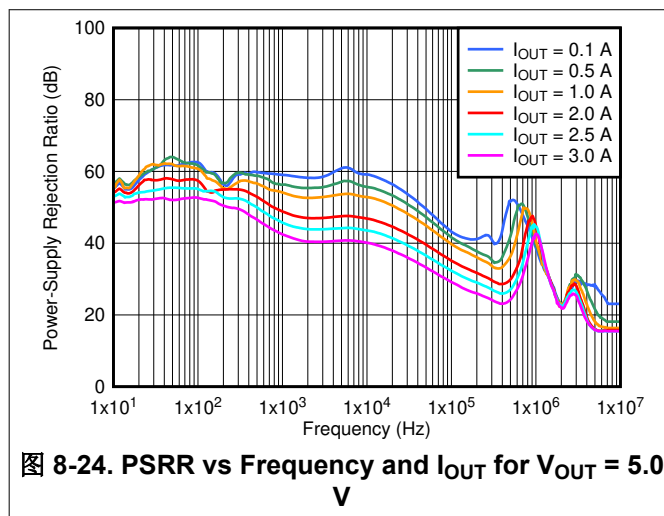
9 Power Supply Recommendations

The TPS7A84 is designed to operate from an input voltage supply range between 1.1 V and 6.5 V. If the input supply is less than 1.4 V, then a bias rail of at least 3.0 V must be used. The input voltage range provides adequate headroom in order for the device to have a regulated output. This input supply must be well regulated. If the input supply is noisy, additional input capacitors with low ESR can help improve output noise performance.

10 Layout

10.1 Layout Guidelines

10.1.1 Board Layout

For best overall performance, place all circuit components on the same side of the circuit board and as near as practical to the respective LDO pin connections. Place ground return connections to the input and output capacitor, and to the LDO ground pin as close to each other as possible, connected by a wide, component-side, copper surface. The use of vias and long traces to the input and output capacitors is strongly discouraged and negatively affects system performance. The grounding and layout scheme illustrated in 图 10-1 minimizes inductive parasitics, and thereby reduces load-current transients, minimizes noise, and increases circuit stability.

A ground reference plane is also recommended and is either embedded in the PCB itself or located on the bottom side of the PCB opposite the components. This reference plane serves to assure accuracy of the output voltage, shield noise, and behaves similar to a thermal plane to spread (or sink) heat from the LDO device when connected to the thermal pad. In most applications, this ground plane is necessary to meet thermal requirements.

10.2 Layout Example

图 **10-1. Example Layout**

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Product Folder Links: *TPS7A84*
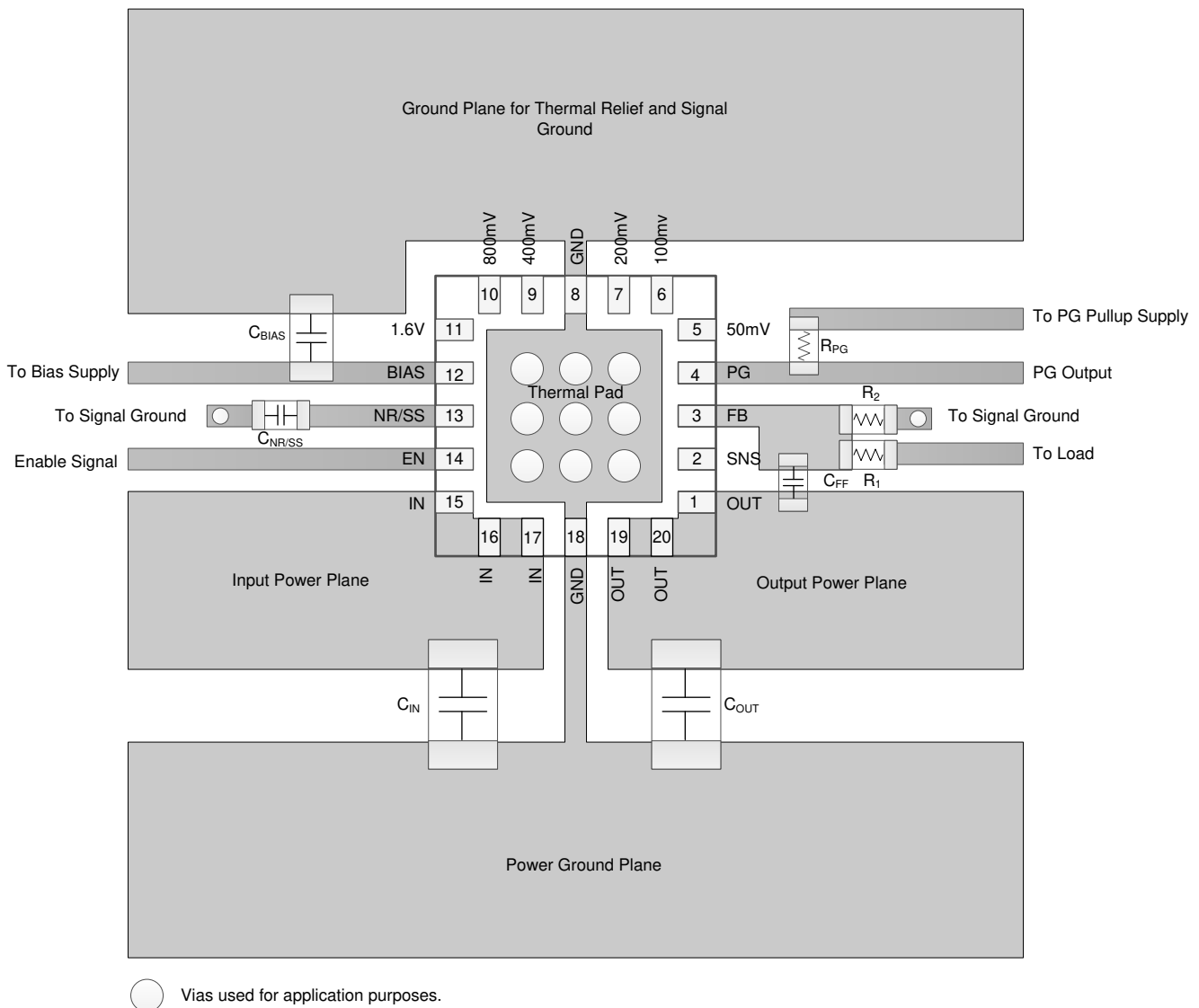
11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

11.1.1.1 Evaluation Modules

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS7A84. The summary information for this fixture is shown in 表 11-1.

表 11-1. Design Kits and Evaluation Modules

NAME	LITERATURE NUMBER
TPS7A8400EVM-753 evaluation module	SBVU028

The EVM can be requested at the Texas Instruments web site through the TPS7A84 product folder.

11.1.1.2 Spice Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TPS7A84 is available through the TPS7A84 product folder under simulation models.

11.1.2 Device Nomenclature

表 11-2. Ordering Information[1]

PRODUCT	DESCRIPTION
TPS7A84**YYYZ**	**YYY** is the package designator. **Z** is the package quantity.

(1)   For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the device product folder at www.ti.com.

11.2 Documentation Support

11.2.1 Related Documentation

For related documentation see the following:

*   Texas Instruments, *TPS3702 High-Accuracy, Overvoltage and Undervoltage Monitor* data sheet
*   Texas Instruments, *TPS7A8400EVM-753 Evaluation Module* user's guide
*   Texas Instruments, *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator* application report
*   Texas Instruments, *6A Current-Sharing Dual LDO* design guide

11.3 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

11.4 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

11.5 Trademarks

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Product Folder Links: *TPS7A84*

11.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.7 术语表

TI 术语表   本术语表列出并解释了术语、首字母缩略词和定义。

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

重要声明和免责声明

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS7A8400RGRR	ACTIVE	VQFN	RGR	20	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	11CI	Samples
TPS7A8400RGRT	ACTIVE	VQFN	RGR	20	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	11CI	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A8400RGRR	VQFN	RGR	20	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
TPS7A8400RGRR	VQFN	RGR	20	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
TPS7A8400RGRT	VQFN	RGR	20	250	180.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
TPS7A8400RGRT	VQFN	RGR	20	250	180.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

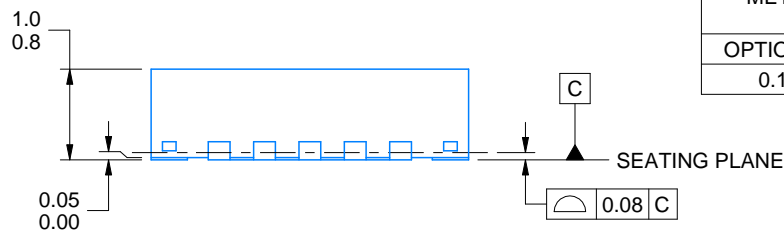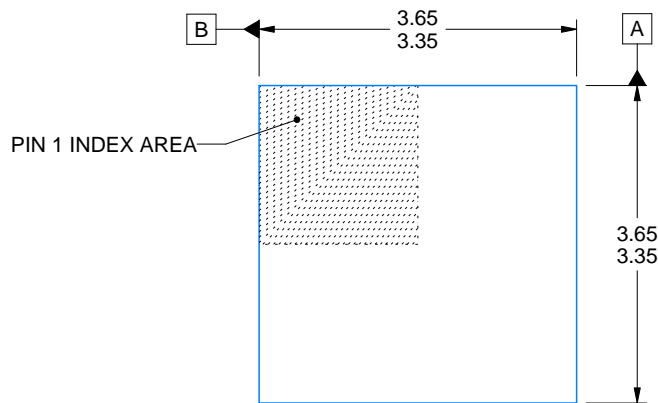| Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7A8400RGRR	VQFN	RGR	20	3000	335.0	335.0	25.0
TPS7A8400RGRR	VQFN	RGR	20	3000	367.0	367.0	35.0
TPS7A8400RGRT	VQFN	RGR	20	250	210.0	185.0	35.0
TPS7A8400RGRT	VQFN	RGR	20	250	182.0	182.0	20.0

RGR 20

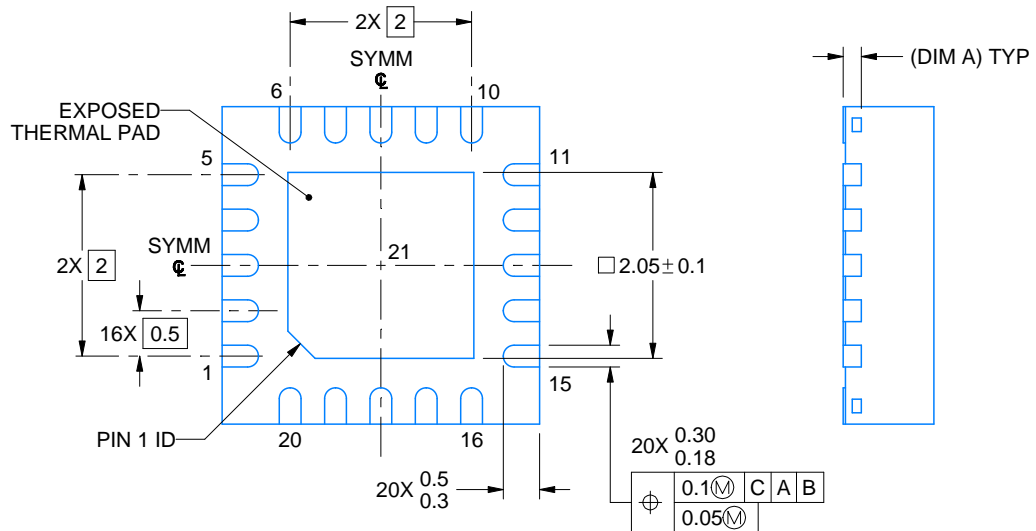**3.5 x 3.5, 0.5 mm pitch**

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4228482/A

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Instruments
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B | 3.65 / 3.35 | A

PIN 1 INDEX AREA

3.65 / 3.35
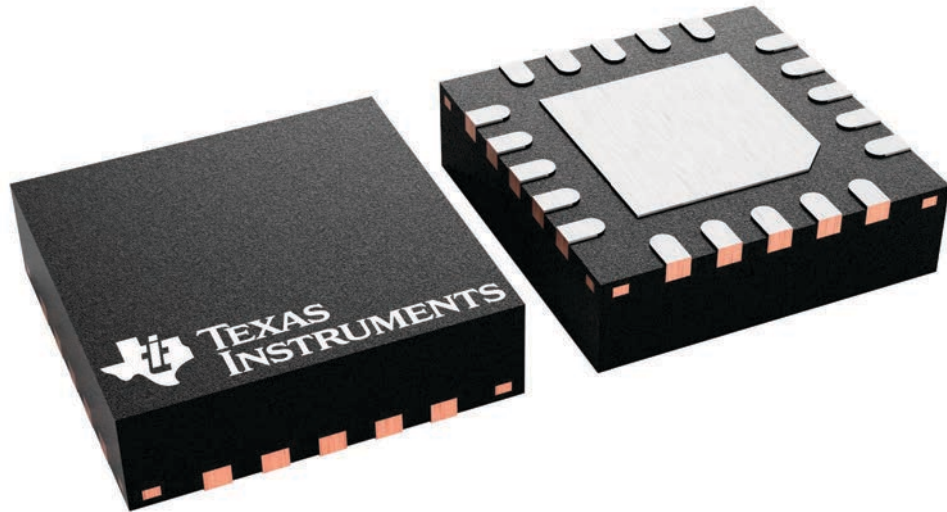
SIDE WALL METAL THICKNESS DIM A	
OPTION 1	OPTION 2
0.1	0.2

1.0 / 0.8

C

SEATING PLANE

0.05 / 0.00

⌒ | 0.08 | C

2X [2]

SYMM ₵

6   10

EXPOSED THERMAL PAD

5   11

2X [2]

SYMM ₵   21   □2.05±0.1

16X [0.5]

1

PIN 1 ID

20   16   15

20X 0.30 / 0.18

20X 0.5 / 0.3

⊕ | 0.1 Ⓜ | C | A | B |
| 0.05 Ⓜ |

(DIM A) TYP
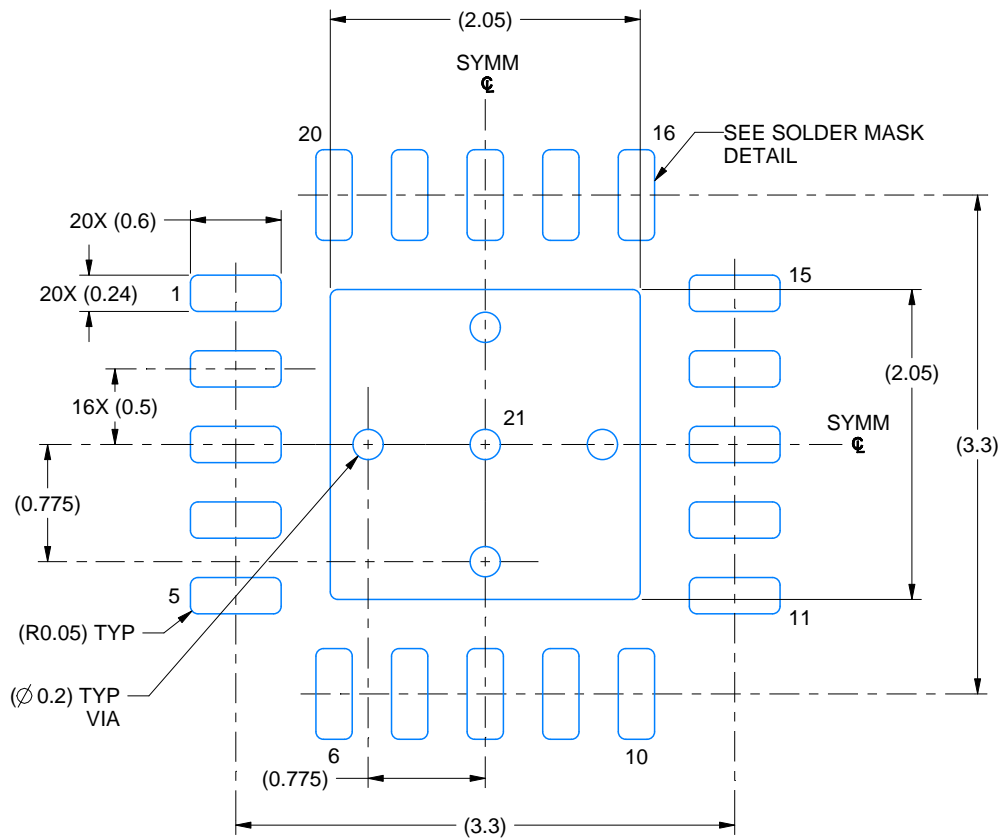
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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

(2.05)

SYMM
℄

20

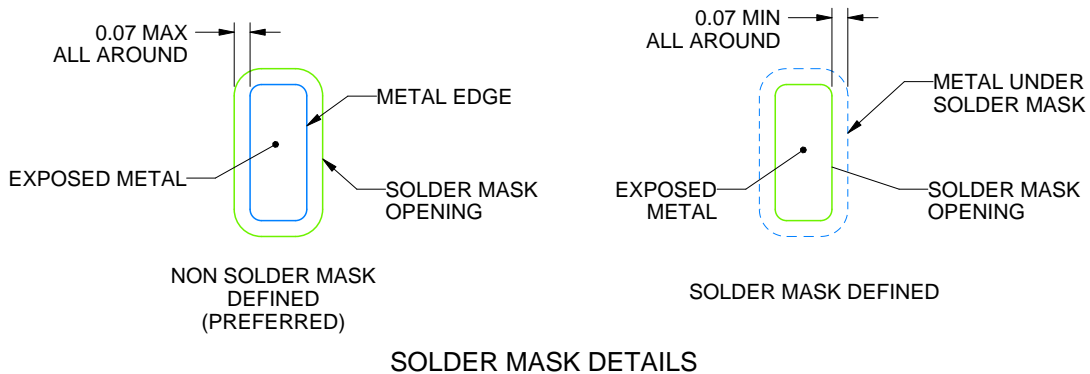16 — SEE SOLDER MASK
DETAIL

20X (0.6)

20X (0.24)   1

15

16X (0.5)

21

(2.05)

SYMM
℄

(3.3)

(0.775)

5

(R0.05) TYP

(⌀ 0.2) TYP
VIA

6   10

11

(0.775)

(3.3)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X

0.07 MAX
ALL AROUND

METAL EDGE

EXPOSED METAL

SOLDER MASK
OPENING

NON SOLDER MASK
DEFINED
(PREFERRED)

0.07 MIN
ALL AROUND

METAL UNDER
SOLDER MASK

EXPOSED
METAL

SOLDER MASK
OPENING

SOLDER MASK DEFINED

SOLDER MASK DETAILS

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NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
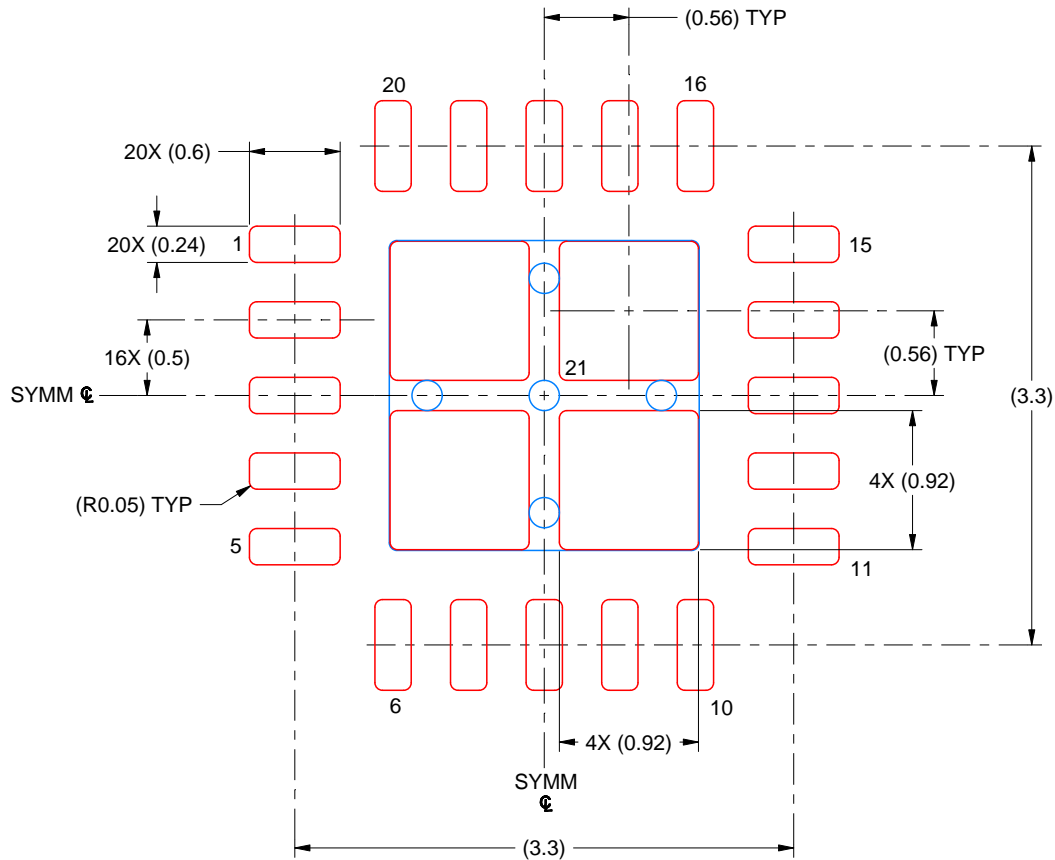
RGR0020A

(0.56) TYP

20

16

20X (0.6)

20X (0.24)   1

15

16X (0.5)

(0.56) TYP

SYMM ℄

21

(3.3)

4X (0.92)

(R0.05) TYP

5

11

6

10

4X (0.92)

SYMM
℄

(3.3)

SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 20X

EXPOSED PAD 21
81% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
   design recommendations.

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